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CS8221 NEW ENHANCED AT (NEAT™) DATA BOOK
82C211/82C212/82C215/82C206 (IPC) CHIPSet™
 994775 994592

- 100% IBM™ PC/AT Compatible New Enhanced CHIPSet™ for 12MHz to 16MHz systems
- Supports 16MHz 80286 operation with only 0.5-0.7 wait states for 100ns DRAMs and 12 MHz operation with 150ns DRAMs, 0 wait state 12MHz operation with 80ns DRAMs
- Separate CPU and AT Bus clocks
- Page Interleaved Memory supports single bank page mode, 2 way and 4 way page interleaved mode
- Integrated Lotus-Intel-Microsoft Expanded Memory Specification (LIM EMS) Memory Controller. Supports EMS 4.0.
- Software Configurable Command Delays, Wait states and Memory Organization
- Optimized for OS/2 operation
- Shadow RAM for BIOS and video ROM to improve system performance
- Complete AT/286 system board requires only 28 logic components plus memory and processor
- Targeted at Desktop PC/ATs, Laptops and CMOS Industrial Control Applications
- Available as four CMOS 84-pin PLCC or 100-pin PFP components.

The CS8221 PC/AT compatible NEAT CHIPSet™ is an enhanced, high performance 4 chip VLSI implementation (including the 82C206 IPC) of the control logic used on the IBM™ Personal Computer AT. The flexible

architecture of the NEAT CHIPSet™ allows it to be used in any 80286 based system.

The CS 8221 NEAT CHIPSet™ provides a complete 286 PC/AT compatible system,

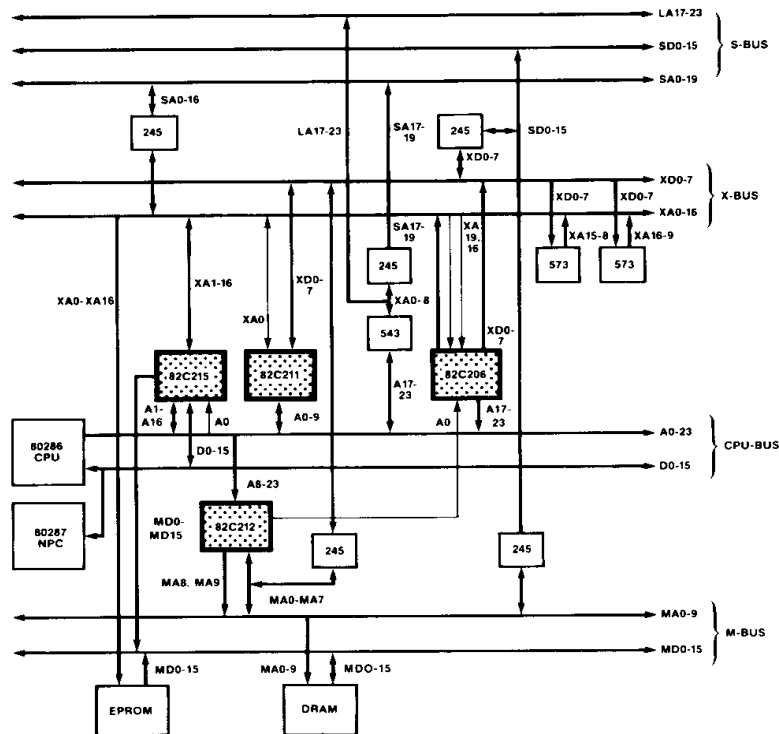


Figure 1. NEAT System Block Diagram

requiring only 24 logic components plus memory devices.

The CS8221 NEAT CHIPSet™ consists of the 82C211 CPU/Bus controller, the 82C212 Page/Interleave and EMS Memory controller, the 82C215 Data/Address buffer and the 82C206 Integrated Peripherals Controller (IPC).

The NEAT CHIPSet™ supports the local CPU bus, a 16 bit system memory bus, and the AT buses as shown in the NEAT System Block Diagram. The 82C211 provides synchronization and control signals for all buses. The 82C211 also provides an independent AT bus clock and allows for dynamic selection between the processor clock and the user selectable AT bus clock. Command delays and wait states are software configurable, providing flexibility for slow or fast peripheral boards.

The 82C212 Page/Interleave and EMS Memory controller provides an interleaved memory sub-system design with page mode operation. It supports up to 8 MB of on-board DRAM with combinations of 64Kbit, 256Kbit and 1Mbit DRAMs. The processor can operate at 16MHz with 0.5–0.7 wait state memory accesses, using 100 nsec DRAMs. This is possible through the Page Interleaved memory scheme. The Shadow RAM feature allows faster execution of code stored in EPROM, by down loading code from EPROM to RAM. The RAM then shadows the EPROM for further code execution. In a DOS environment, memory above 1Mb can be treated as LIM EMS memory.

The 82C215 Data/Address buffer provides the buffering and latching between the local CPU address bus and the Peripheral address bus. It also provides buffering between the local

CPU data bus and the memory data bus. The parity bit generation and error detection logic resides in the 82C215.

The 82C206 Integrated Peripherals Controller is an integral part of the NEAT CHIPSet™. It is described in the 82C206 Integrated Peripherals Controller data book.

System Overview

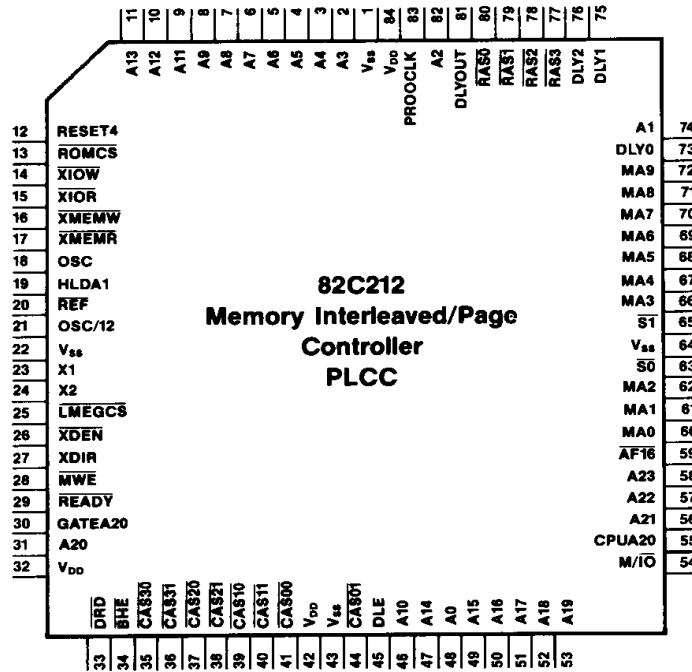
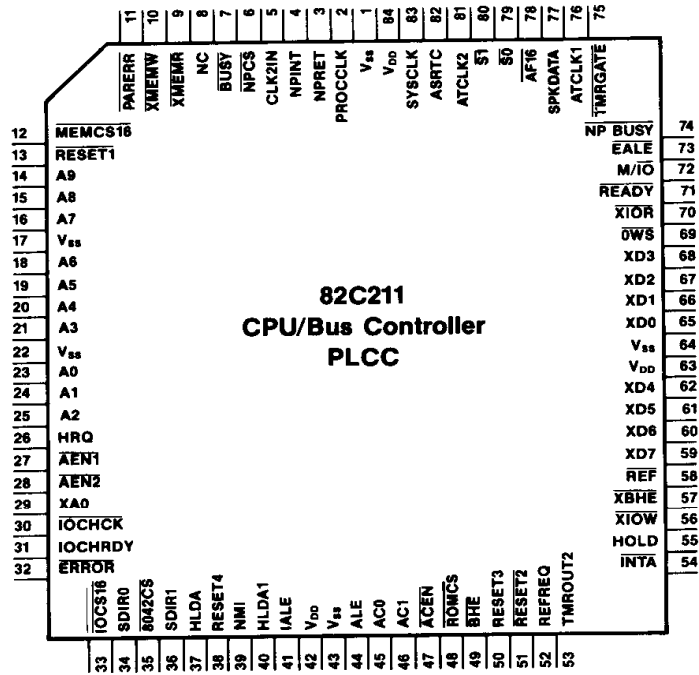
The CS8221 NEAT CHIPSet™ is designed for use in 12 to 16 MHz 80286 based systems and provides complete support for the IBM PC/AT bus. There are four buses supported by the CS8221 NEAT CHIPSet™ as shown in Figure 1: CPU local bus (A and D), system memory bus (MA and MD), I/O channel bus (SA and SD), and X bus (XA and XD). The system memory bus is used to interface the CPU to the DRAMs and EPROMs controlled by the 82C212. The I/O channel bus refers to the bus supporting the AT bus adapters which could be either 8 bit or 16 bit devices. The X bus refers to the peripheral bus to which the 82C206 IPC and other peripherals are attached in an IBM PC/AT.

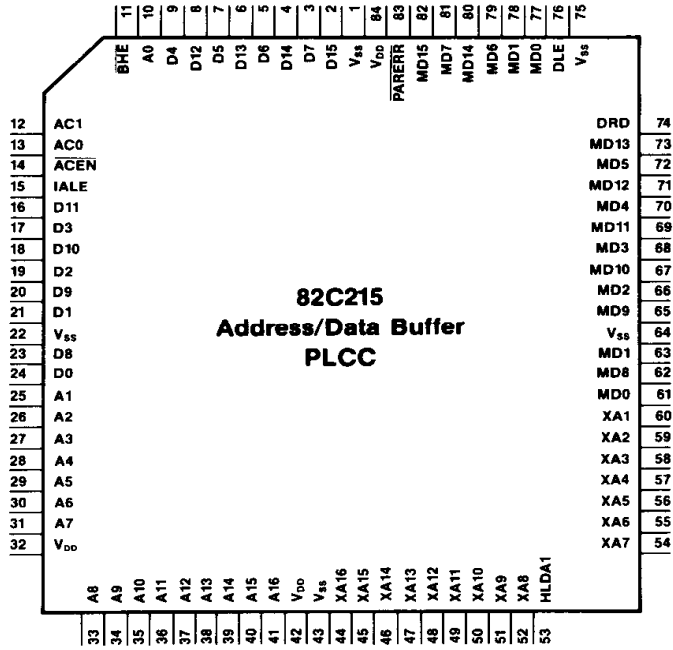
Notation and Glossary

The following notations are used to refer to the configuration and diagnostics registers internal to the 82C211 and 82C212:

REGnH denotes the internal register of index n in hexadecimal notation.

REGnH<x:y> denotes the bit field from bits x to y of the internal register with index n in hexadecimal notation.





82C211 Pin Description

Pin No.	Pin Type	Symbol	Description
Clocks			
5	I	CLK2IN	CLOCK 2 input from a TTL crystal oscillator having a maximum of twice the rated frequency of the 80286 processor clock.
2	O	PROCCLK	PROCESSOR CLOCK output for the 80286 and the 82C212. It is derived from CLK2IN. It can also be programmed to be derived from ATCLK.
76	I	ATCLK1	AT Bus Clock 1 input source from crystal or oscillator. This clock input is used for the AT bus operation and is only required if the AT bus state machine clock, BCLK (internal) will not be derived from CLK2IN. This clock input should be tied low if not used. Its frequency should be lower than CLK2IN. BCLK is the AT bus state machine clock and can be programmed to be equal to ATCLK.
81	O	ATCLK2	AT Bus Clock 2 output is connected to the crystal (if a crystal is used to generate AT bus clock). A series damping resistor of 10 ohms should be used to reduce amplitude of the resonant circuit. It should be left open if a TTL oscillator is used.
83	O	SYSCLK	AT System Clock output is buffered to drive the SYSCLK line on the AT bus I/O channel. It is half the frequency of BCLK and should be between 6 and 8 MHz for maintaining correct AT I/O bus timing compatibility with the IBM™ PC/AT.
Control			
13	I	RESET1	RESET1 is an active low input generated by the power good signal of the power supply. When low, it activates RESET3 and RESET4. RESET1 is latched internally.
51	I	RESET2	RESET2 is an active low input generated from the keyboard controller (8042/8742) for a "warm reset" not requiring the system power to be shut off. It forces a CPU reset by activating RESET3.
38	O	RESET4	RESET4 is an active high output used to reset the AT bus, 82C206 IPC, 8042 keyboard controller, 82C212 memory controller. It is synchronized with the processor clock.
50	O	RESET3	RESET3 is an active high output to the 80286 when RESET1 or RESET2 is active. It is also activated when shut-down condition in the CPU is detected. RESET3 will stay active for at least 16 PROCLK cycles.

82C211 Pin Description (Continued)

Pin No.	Pin Type	Symbol	Description
CPU Interface			
71	I/O	READY	READY as an output, is driven low to terminate the current CPU cycle after IOCHRDY is high and \overline{OWS} is high, or if "time out" condition is detected. During all other cycles, it is an input from the 82C212. It is an open collector output requiring an external pull-up resistor of 1K Ω and is connected to the 80286 READY pin.
79, 80	I	$\overline{S0}, \overline{S1}$	STATUS is an active low input from the CPU. The status signals are used by the 82C211 to determine the state of the CPU. Pull up resistors of 10K Ω each should be provided.
72	I	$\overline{M/IO}$	MEMORY INPUT/OUTPUT is the signal from the CPU. When high, it indicates a memory access, when low it indicates an I/O access. It is used to generate memory and I/O signals for the system. A 10K Ω pull up resistor is recommended.
55	O	HOLD	CPU HOLD REQUEST is an active high output to the CPU. It is activated during DMA, Master or refresh cycles.
37	I	HLDA	HOLD ACKNOWLEDGE is an active high input generated by the CPU to indicate to the requesting master that it has relinquished the bus. When active, it forces all commands (IOR, IOW, MEMR, MEMW, INTA) to be tri-stated.
49	I/O	\overline{BHE}	BYTE HIGH ENABLE is an active low signal which indicates the transfer of data on the upper byte of the data bus. In conjunction with A0, it is input during CPU cycles and in conjunction with XA0, it is output during DMA, MASTER cycles. A pull up resistor of 10K Ω is required.
39	O	NMI	NON MASKABLE INTERRUPT is an active high output to the NMI pin of the CPU and is generated by the 82C211 to invoke a non-maskable interrupt.
41	O	IALE	ADDRESS LATCH ENABLE (INTERNAL) is an active high output synchronized with PROCCLK and controls address latches used to hold addresses during bus cycles. It is not issued for halt bus cycles.

82C211 Pin Description (Continued)

Pin No.	Pin Type	Symbol	Description
I/O Channel Interface			
31	I	IOCHRDY	I/O CHANNEL READY is an active high input from the AT bus. When low it indicates a not ready condition and inserts wait states in AT-I/O or AT-memory cycles. When high it allows termination of the current AT-bus cycle. A series damping resistor of 53Ω at the AT bus connector is recommended to limit the negative under shoot. A 1KΩ pull up resistor is required for this open collector line.
30	I	IOCHCK	I/O CHANNEL CHECK is an active low input from the AT bus causing an NMI to be generated if enabled. It is used to signal an I/O error condition from a device residing on the AT bus. A 10KΩ pull up resistor is required.
11	I	PARERR	PARITY ERROR is an active low input from the 82C215 which causes an NMI if enabled. It indicates a parity error in local system memory.
44	O	ALE	ADDRESS LATCH ENABLE is an active high output to the AT bus and is synchronized with the AT state machine clock. It controls the address latches used to hold the addresses during bus cycles. This signal should be buffered to drive the AT bus.
73	O	EALE	EXTERNAL ADDRESS LATCH ENABLE is an active low output used to latch the CPU A17-A23 address lines to the LA17-LA23 lines on the AT bus.
DMA Interface			
40	O	HLDA1	HOLD ACKNOWLEDGE 1 is an active high output when a bus cycle is granted in response to HOLD REQUEST 1.
26	I	HRQ	HOLD REQUEST is an active high input when DMA/Master is requesting a bus cycle. For an AT compatible architecture, it should be connected to the HOLD REQUEST signal from DMA1 and DMA2.
27	I	AEN1	ADDRESS ENABLE 1 is an active low input from one of the two DMA controllers enabling the address latches for 8 bit DMA transfers.
28	I	AEN2	ADDRESS ENABLE 2 is an active low input from one of the two DMA controllers enabling the address latches for 16 bit DMA transfers.
48	I	ROMCS	ROM CHIP-SELECT is an active low input from the 82C212. It is used to disable parity checks for local ROM cycles.

82C211 Pin Description (Continued)

Pin No.	Pin Type	Symbol	Description
Bus Inputs			
12	I	$\overline{\text{MEMCS16}}$	MEMORY CHIP SELECT 16 is an active low input from the AT bus indicating a 16 bit memory transfer. If high it implies an 8 bit memory transfer. A pull up resistor of 330 Ω is required.
33	I	$\overline{\text{IOCS16}}$	I/O CHANNEL SELECT 16 is an active low input from the AT bus indicating a 16 bit I/O transfer. If high it implies an 8 bit I/O transfer. A pull up resistor of 330 Ω is required.
69	I	$\overline{\text{OWS}}$	ZERO WAIT STATES is an active low input from the AT bus, causing immediate termination of the current AT bus cycle. Memories requiring zero wait states use this line to speed up memory cycles. It requires a 330 Ω pull up resistor.
Device Decode			
35	O	$\overline{\text{8042CS}}$	8042 CHIP SELECT is an active low signal for the keyboard controller chip select.
82	O	ASRTC	ADDRESS STROBE to Real Time Clock is an active high signal used on the 82C206.
Refresh			
52	I	REFREQ	REFRESH REQUEST is an active high input initiating a DRAM refresh sequence. It is generated by the 8254 compatible timer controller #1 of the 82C206 IPC in a PC/AT implementation.
58	I/O	$\overline{\text{REF}}$	REFRESH is an active low signal. As an open drain output, it initiates a refresh cycle for the DRAMs. As an input, it can be used to force a refresh cycle from an I/O device. An external pull up of 620 Ω is required.
X Bus Interface			
9	I/O	$\overline{\text{XMEMR}}$	X BUS MEMORY READ is an active low control strobe directing memory to place data on the data bus. It is an output if the CPU is controlling the bus and is an input if a DMA controller is in control of the bus.
10	I/O	$\overline{\text{XMEMW}}$	X BUS MEMORY WRITE is an active low control strobe directing memory to accept data from the data bus. It is an output if the CPU is controlling the bus and is an input if a DMA controller is in control of the bus.

82C211 Pin Description (Continued)

Pin No.	Pin Type	Symbol	Description
70	I/O	\overline{XIOR}	X BUS I/O READ is an active low strobe directing an I/O port to place data on the data bus. It is an output if the CPU is controlling the bus and is an input if a DMA controller is in control of the bus.
56	I/O	\overline{XIOW}	X BUS I/O WRITE is an active low strobe directing an I/O port to accept data from the data bus. It is an output if the CPU is controlling the bus and is an input if a DMA controller is in control of the bus.
57	I/O	\overline{XBHE}	X BYTE HIGH ENABLE is an active low signal indicating the high byte has valid data on the bus. It is an output when the CPU is in control of the bus and is an input when a DMA controller is in control of the bus. A 4.7K Ω pull-up resistor is required on this line.
59-62 65-68	I/O I/O	$XD\langle 7:4 \rangle$ $XD\langle 0:3 \rangle$	X DATA BUS bits $\langle 7:0 \rangle$
8	—	NC	No Connect
75	O	TMRGATE	TIMER GATE is an active high output that enables the timer on the 8254 compatible counter timer in the 82C206 to enable the tone signal for the speaker.
53	I	TMROUT2	TIMER OUT 2 is an active high input from the 8254 compatible counter timer in the 82C206 that can be read from port B.
77	O	SPKDATA	SPEAKER DATA is an active high output used to gate the 8254 compatible tone signal of the 82C206 to the speaker.
54	O	\overline{INTA}	INTERRUPT ACKNOWLEDGE is an active low output to the 82C206 interrupt controller. It is also used to direct data from the X to S bus during an interrupt acknowledge cycle.
Buffer Control			
34	O	SDIR0	SYSTEM BUS DIRECTION 0 for the low byte. A low sets the data path from the S bus to the M bus. A high sets the data path from the M bus to the S bus.
36	O	SDIR1	SYSTEM BUS DIRECTION 1 for the high byte. A low sets the data path from the S bus to the M bus. A high sets the data path from the M bus to the S bus.
47	O	\overline{ACEN}	ACTION CODE ENABLE is an active low output that validates the action code signals $AC\langle 1, 0 \rangle$ that are used by the 82C215 address/data buffer.

82C211 Pin Description (Continued)

Pin No.	Pin Type	Symbol	Description
46, 45	O	AC<1, 0>	ACTION CODE is a two bit encoded output command for bus size control and byte assembly operations performed in the 82C215.
Memory Control			
78	I	$\overline{\text{AF16}}$	AF16 is an active low input indicating that the current cycle is a local bus cycle. A high indicates an AT bus cycle. A 10K Ω pull up resistor is required.
23-25 18-21 14-18	I/O	A<0:2> A<3:6> A<7:9>	ADDRESS lines A0-A9 are input from the CPU. These lines are output during refresh. A1 is used to detect shut down condition of the CPU. A0 is used to generate the enable signal for the data bus transceivers.
29	I/O	XA0	ADDRESS line XA0 from the X bus. It is an output during CPU accesses on the X bus and is an input for 8 bit DMA cycles.
CoProcessor Interface			
6	O	$\overline{\text{NPCS}}$	NUMERIC COPROCESSOR CHIP SELECT is an active low output signal used to select the internal registers of the 80287 NPX.
7	O	$\overline{\text{BUSY}}$	BUSY is an active low output to the CPU initiated by the 80287 NPX, indicating that it is busy. A 4.7K Ω pull up resistor is required.
74	I	$\overline{\text{NPBUSY}}$	NUMERIC COPROCESSOR BUSY is an active low input from the NPX, indicating that it is currently executing a command. It is used to generate the BUSY signal to the CPU. A 4.7K Ω pull up resistor is required.
32	I	$\overline{\text{ERROR}}$	ERROR is an active low input from the NPX indicating that an unmasked error condition exists. A 4.7K Ω pull up resistor is required.
4	O	NPINT	NUMERIC COPROCESSOR INTERRUPT is an active high output . It is an interrupt request from the 80287 and is connected to the IRQ13 line of the 82C206 IPC in a PC/AT environment. A 10K Ω pull up resistor is required.

82C211 Pin Description (Continued)

Pin No.	Pin Type	Symbol	Description
3	O	NPRESET	NUMERICAL PROCESSOR RESET is an active high reset to the 80287. It is active when RESET4 is active or when a write operation is made to Port 0F1H. In the later case, it is active for the period of the command.
Power Supplies			
42, 63, 84	—	VDD	POWER SUPPLY.
1, 17, 22 43, 64	—	VSS	GROUND.

82C212 Pin Description

Pin No.	Pin Type	Symbol	Description
Clocks and Control			
83	I	PROCCLK	PROCESSOR CLOCK input from the 82C211
23	I	X1	CRYSTAL 1 input from the 14.31818 MHz crystal.
24	O	X2	CRYSTAL 2 output to the 14.31818 MHz crystal.
18	O	OSC	OSCILLATOR output for the system clock at 14.31818 MHz and has a drive capability of 24mA.
21	O	OSC/12	OSCILLATOR divided by 12 is an output with a clock frequency equal to 1/12 of the crystal frequency across the X1, X2 pins.
12	I	RESET4	RESET 4 is the active high reset input from the 82C211. It resets the configuration registers to their default values. When active, RAS<0:3> and CAS<00:31> remain high, OSC and OSC/12 remain inactive.
20	I	REF	REFRESH is an active low input for DRAM refresh control from the 82C211. It initiates a refresh cycle for the DRAMs.
65, 63	I	S<1, 0>	STATUS input lines from the CPU are active low. These lines are monitored to detect the start of a cycle.
54	I	M/I \bar{O}	MEMORY I/O signal from the CPU. If high it indicates a memory cycle. If low, it indicates an I/O cycle.
15	I	XIOR	I/O READ command, input active low.
14	I	XIOW	I/O WRITE command, input active high.
17	I	XMEMR	X BUS MEMORY READ command, input active low.
16	I	XMEMW	X BUS MEMORY WRITE command, input active low.
19	I	HLDA1	HOLD ACKNOWLEDGE 1 is an active high input from the 82C211. It is used to generate RAS and CAS signals for DMA cycles, in response to a hold request.
13	O	ROMCS	ROM CHIP SELECT is an active low chip select output to the BIOS EPROM. It can be connected to the output enable pin of the EPROM.
48, 74, 82		A<0:2>	
2-8		A<3:9>	
46		A10	
9-11	I	A<11:13>	ADDRESS input lines A<0:23> from the CPU local bus.
47		A14	
49-53		A<15:19>	
55-58		A<20:23>	

82C212 Pin Description (Continued)

Pin No.	Pin Type	Symbol	Description
34	I	$\overline{\text{BHE}}$	BYTE HIGH ENABLE is an active low input from the CPU for transfer of data on the upper byte.
29	I/O	$\overline{\text{READY}}$	READY is the system ready signal to the CPU. It is an active low output after requested memory or I/O data transfer is completed. It is an input when the current bus cycle is an AT bus cycle and is an output for local memory and I/O cycles.
59	O	$\overline{\text{AF16}}$	AF16 is an active low output asserted on local memory (EPROM or DRAM) cycles. It is high for all other cycles. This signal is sampled by the 82C211.
DRAM Interface			
77-80	O	$\overline{\text{RAS}}\langle 3:0 \rangle$	ROW ADDRESS STROBES 3 to 0 are active low outputs used as RAS signals to the DRAMs for selecting different banks. RAS3 selects the highest bank and RAS0 selects the lowest bank. These signals should be buffered and line terminated with 75Ω resistors to reduce ringing before driving the DRAM RAS lines.
41	O	$\overline{\text{CAS00}}$	COLUMN ADDRESS STROBE 00 is an active low output used to select the low byte DRAMs of bank 0. This signal should be line terminated with a 75Ω resistor to reduce ringing before driving the DRAM CAS line.
44	O	$\overline{\text{CAS01}}$	COLUMN ADDRESS STROBE 01 is an active low output used to select the high byte DRAMs of bank 0. This signal should be line terminated with a 75Ω resistor to reduce ringing before driving the DRAM CAS line.
39	O	$\overline{\text{CAS10}}$	COLUMN ADDRESS STROBE 10 is an active low output used to select the low byte DRAMs of bank 1. This signal should be line terminated with a 75Ω resistor to reduce ringing before driving the DRAM CAS line.
40	O	$\overline{\text{CAS11}}$	COLUMN ADDRESS STROBE 11 is an active low output used to select the high byte DRAMs of bank 1. This signal should be line terminated with a 75Ω resistor to reduce ringing before driving the DRAM CAS line.
37	O	$\overline{\text{CAS20}}$	COLUMN ADDRESS STROBE 20 is an active low output used to select the low byte DRAMs of bank 2. This signal should be line terminated with a 75Ω resistor to reduce ringing before driving the DRAM CAS line.

82C212 Pin Description (Continued)

Pin No.	Pin Type	Symbol	Description
38	O	$\overline{\text{CAS21}}$	COLUMN ADDRESS STROBE 21 is an active low output used to select the high byte DRAMs of bank 2. This signal should be line terminated with a 75Ω resistor to reduce ringing before driving the DRAM CAS line.
35	O	$\overline{\text{CAS30}}$	COLUMN ADDRESS STROBE 30 is an active low output used to select the low byte DRAMs of bank 3. This signal should be line terminated with a 75Ω resistor to reduce ringing before driving the DRAM CAS line.
36	O	$\overline{\text{CAS31}}$	COLUMN ADDRESS STROBE 31 is an active low output used to select the high byte DRAMs of bank 3. This signal should be line terminated with a 75Ω resistor to reduce ringing before driving the DRAM CAS line.
28	O	$\overline{\text{MWE}}$	MEMORY WRITE ENABLE is an active low output for DRAM write enable.
45	O	DLE	DATA LATCH ENABLE is an active high output used to enable the local memory data buffer latch in the 82C215.
33	O	$\overline{\text{DRD}}$	DATA READ is an active low output used to transfer data from the memory bus to the local CPU bus in the 82C215. If high it sets the data path from the local CPU bus to the memory bus.
81	O	DLYOUT	DELAY LINE OUT is an active high output to the delay line for generating the DRAM control signals.
73, 75, 76	I	DLY<0:2>	DELAY IN 0, 1, 2 are active high inputs from the first to third taps on the delay line used to generate DRAM control signals.
26	O	$\overline{\text{XDEN}}$	X DATA BUFFER ENABLE is an active low output asserted during I/O accesses to locations 22H and 23H. These locations contain the index and data registers for the NEAT CHIPSet™. It is used to enable the buffers between the XD and MA buses for accessing the 82C212 internal registers.
27	O	$\overline{\text{XDIR}}$	X BUS DIRECTION is used to control the drivers between the X and S buses. The driver should be used such that data flow is from the S to X bus when $\overline{\text{XDIR}}$ is high and in the other direction when $\overline{\text{XDIR}}$ is low.
71-72	O	MA<8:9>	MULTIPLEXED DRAM ADDRESS lines MA8, MA9. These lines should be buffered and line terminated with 75Ω resistors before driving the DRAM address lines.

82C212 Pin Description (Continued)

Pin No.	Pin Type	Symbol	Description
66-70 60-62	I/O	MA<3:7> MA<0:2>	MULTIPLICED DRAM ADDRESS lines MA0 to MA7. Also used as bi-directional lines to read/write to the internal registers of the 82C212. An external 74ALS245 buffer is required to isolate this path during normal DRAM operation. These lines should be buffered and line terminated with 75Ω resistors before driving the DRAM address lines.
Miscellaneous			
31	I/O	GA20	ADDRESS line 20 is the gated A20 bit which is controlled by GATEA20.
30	I	GATEA20	GATE ADDRESS 20 is an input used to force A20 low when GATEA20 is low. When high it propagates CPUA20 onto the A20 line. It is used to keep address under 1Mb during DOS operation.
25	O	$\overline{\text{LMEGCS}}$	LOW MEG CHIP SELECT is an unlatched active low output asserted when the low Meg memory address space (0 to 1024 Kbytes) is accessed or during refresh cycles. It is used to disable $\overline{\text{SMEMR}}$ and $\overline{\text{SMEMW}}$ signals on the AT bus if accesses are made beyond the 1Mbyte address space to maintain PC and PC/XT compatibility.
Power and Ground			
32, 42, 84	—	VDD	POWER SUPPLY.
1, 22, 43, 64	—	VSS	GROUND.

82C215 Pin Description

Pin No.	Pin Type	Symbol	Description
Controls			
14	I	\overline{ACEN}	ACTION CODE ENABLE is an active low input from the 82C211 that validates the action codes.
12, 13	I	AC<1:0>	ACTION CODES input from the 82C211 are used for bus sizing and byte assembly operations. They are discussed in Section 1.2.4.
76	I	DLE	DATA LATCH ENABLE is an active high input from the 82C212 used to enable the local memory data buffer latch.
74	I	\overline{DRD}	DATA READ is an active low input from the 82C212 used to transfer data from the M data bus to the CPU data bus. If high, it sets the data path from the CPU data bus to the M data bus.
53	I	HLDA1	HOLD ACKNOWLEDGE 1 is an active high input from the 82C211 used for address and data direction control during DMA cycles.
15	I	IALE	ADDRESS LATCH ENABLE (INTERNAL) is an active high input from the 82C211 used to latch the CPU address lines on to the X address lines.
11	I	\overline{BHE}	BYTE HIGH ENABLE is an active low input from the CPU. It is used to enable the high byte parity checking.
10	I	A0	ADDRESS line A0 is input from the CPU. It is used to enable the low byte parity checking.
Address			
25-31	I/O	A<1:7>	ADDRESS lines A1-A16 from the CPU. They are input during CPU and refresh cycles and output during DMA/Master cycles.
33-41	I/O	A<8:16>	
44-52	I/O	XA<16:8>	X ADDRESS lines XA16-XA1 (latched) are connected to the peripheral bus in the IBM™ PC/AT architecture.
54-60	I/O	XA<7:1>	
Data			
2, 4, 6, 8, 16, 18, 20, 23, 3, 5, 7, 9, 17, 19, 21, 24	I/O	D<15:0>	DATA lines D15-D0 from the CPU.

82C215 Pin Description (Continued)

Pin No.	Pin Type	Symbol	Description
82, 80, 73, 71, 69, 67, 65, 62, 81, 79, 72, 70, 68, 66, 63, 61	I/O	MD<15:0>	MEMORY DATA lines MD15-MD0 from the memory bus.
Parity			
78, 77	I/O	MP1, MP0	MEMORY PARITY bits MP1, MP0 are the parity bits for the high and low order bytes of the system DRAMs. These lines are input during memory operations for parity error detection and are output during memory write operations for parity generation.
83	O	$\overline{\text{PARERR}}$	PARITY ERROR is an active low output to the 82C211 which goes active upon detecting a parity error during a system memory read operation. It is used to generate a non-maskable interrupt to the CPU.
Power and Ground			
32, 42, 84	—	VDD	POWER
1, 22, 43 64, 75	—	VSS	GROUND

1. 82C211 BUS CONTROLLER

1.1 Features

- Clock generation with software speed selection.
- Optional independent AT bus clock.
- CPU interface and bus control.
- Programmable command delays and wait state generation.
- Port B register.

1.2 Functional Description

The 82C211 Bus Controller consists of the following functional sub-modules as illustrated in figure 1.1:

- Reset and Shut down logic
- Clock generation and selection logic

- CPU state machine, AT bus state machine and bus arbitration logic
- Action Codes generation logic
- Port B register and NMI logic
- DMA and Refresh logic
- Numeric Coprocessor interface logic
- Configuration registers

1.2.1 Reset and Shut Down Logic

Two reset inputs RESET1 and RESET2 are provided on the 82C211 bus controller. RESET1 is the Power Good signal from the power supply. When RESET1 is active, the 82C211 asserts RESET3 and RESET4 for a system reset. RESET2 is generated from the 8042 (or 8742) keyboard controller when a "warm reset" is required. The warm reset activates RESET3 to reset the 80286 CPU.

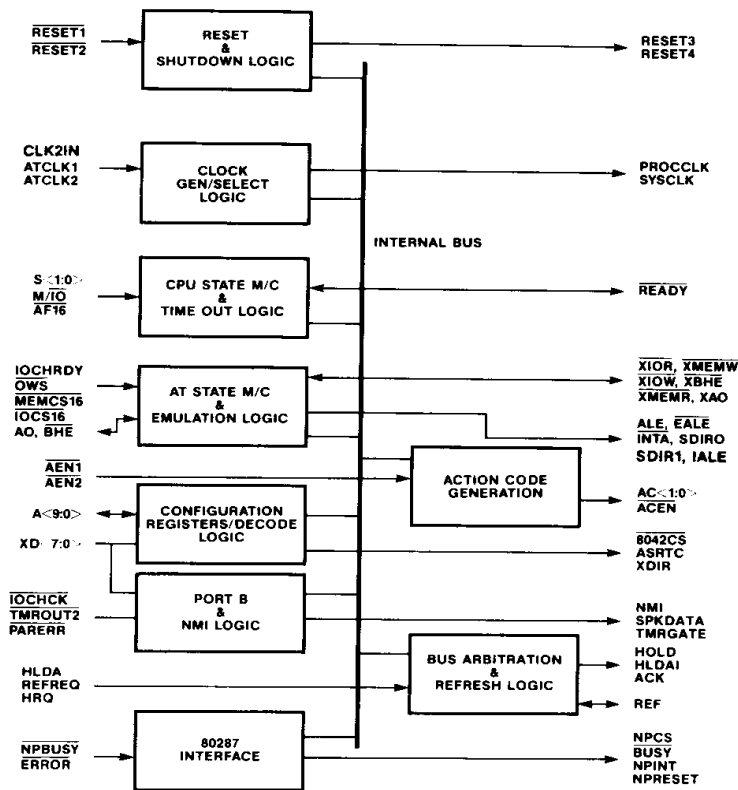


Figure 1.1 82C211 Block Diagram

RESET3 is also activated by the 82C211 when a shut down condition is detected in the CPU. Additionally, a low to high transition in REG60<5> causes RESET3 to be active after the current I/O command goes inactive. RESET3 is asserted for at least 16 PROCCLK cycles and then deasserted. RESET4 is used to reset the AT bus, 82C206 IPC, 8042 keyboard controller and the 82C212 memory controller. It is synchronized with respect to PROCCLK and is asserted as long as the Power Good signal is held low.

After a shut down condition is detected, RESET3 is asserted and held high for at least 16 PROCCLK cycles and then deasserted. RESET3 resulting from a shut down condition is synchronous with PROCCLK, ensuring proper CPU operation. Both RESET3 and RESET4 meet the setup and hold timing requirements of the 80286 CPU.

1.2.2 Clock Generation and Selection Logic

The 82C211 provides a flexible clock selection scheme as shown in Figure 1.2. It has two input clocks; CLK2IN and ATCLK. CLK2IN is driven from a TTL crystal oscillator, running at a maximum of twice the processor clock (PROCCLK) frequency. ATCLK is derived from a crystal. Typically, it should be of a lower frequency than CLK2IN. ATCLK and CLK2IN can be selected under program control.

The 82C211 generates processor clock, PROCCLK, for driving the CPU state machine and interface. SCLK (internal) is PROCCLK/2 and is in phase with the internal states of the 80286. BCLK (internal) is the AT bus state machine clock and is used for the AT bus interface. SYSCLK is the AT bus system clock and is always BCLK/2.

PROCCLK can be derived from CLK2IN or from ATCLK. In the synchronous mode, both PROCCLK and BCLK are derived from CLK2IN, so that the processor state machine and the AT bus state machine run synchronous. In the asynchronous mode, BCLK is generated from the ATCLK and PROCCLK is generated from CLK2IN or the ATCLK. In this case, the processor and AT bus state machines run asynchronous to each other. The following clock selections are possible:

Synchronous mode

1. PROCCLK = BCLK = CLK2IN
SYSCLK = BCLK/2 = CLK2IN/2
2. PROCCLK = CLK2IN
BCLK = CLK2IN/2
SYSCLK = BCLK/2 = CLK2IN/4
3. PROCCLK = BCLK = CLK2IN/2
SYSCLK = BCLK/2 = CLK2IN/4

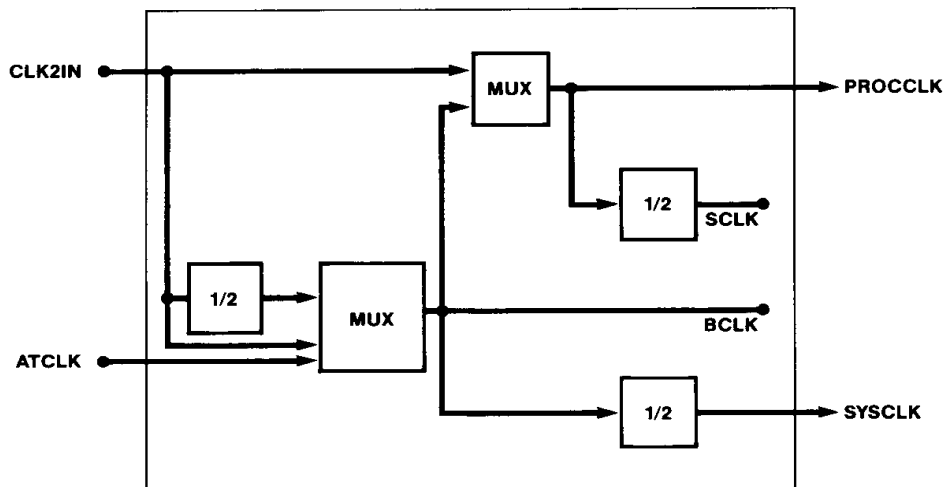


Figure 1.2 Clock Selection Block Diagram

Asynchronous mode

1. PROCCLK = CLK2IN
 BCLK = ATCLK
 SYSCLK = BCLK/2 = ATCLK/2
2. PROCCLK = ATCLK
 BCLK = ATCLK
 SYSCLK = BCLK/2 = ATCLK/2.

Under normal operation, CLK2IN should be selected as the processor clock (PROCCLK) to allow the processor to run at full speed. BCLK can either be a sub-division of CLK2IN or the ATCLK. ATCLK may be selected to generate PROCCLK only when it is desired to slow down the processor for timing dependent code execution. Once the options for clock switching are set, the switching occurs with clean transition in the asynchronous or synchronous mode. During clock switching, no phases of PROCCLK are less

than the minimum value or greater than the maximum value specified for the 80286 CPU. The clock source selection is made by writing to REG62H<0:1> first and then to REG60H<4>, which default to: PROCCLK = CLK2IN, SYSCLK = CLK2IN/4.

Figures 1.3 and 1.4 illustrate the sequence of events that switch PROCCLK from high to low speed and from low to high speed, upon receiving a request from the configuration register. In Figure 1.3, the falling edge (A) of PROCCLK is used to latch the command inactive condition (1). On the falling edge (B), CLK2IN is disabled on the PROCCLK line. This ensures that clock switching will occur when PROCCLK is low. Once CLK2IN has been disabled, the first rising edge (C) of BCLK latches this condition as denoted by sequence (2). BCLK then enables itself on the PROCCLK line on the falling edge (D) as

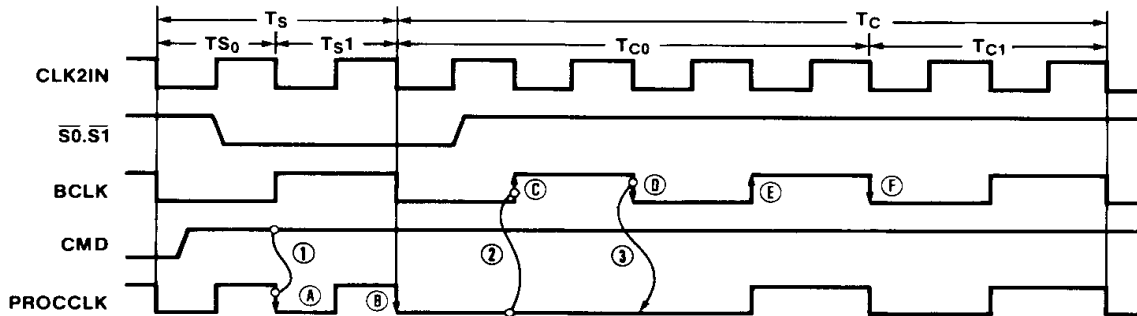


Figure 1.3 Sequence Diagram for High to Low Frequency Transition

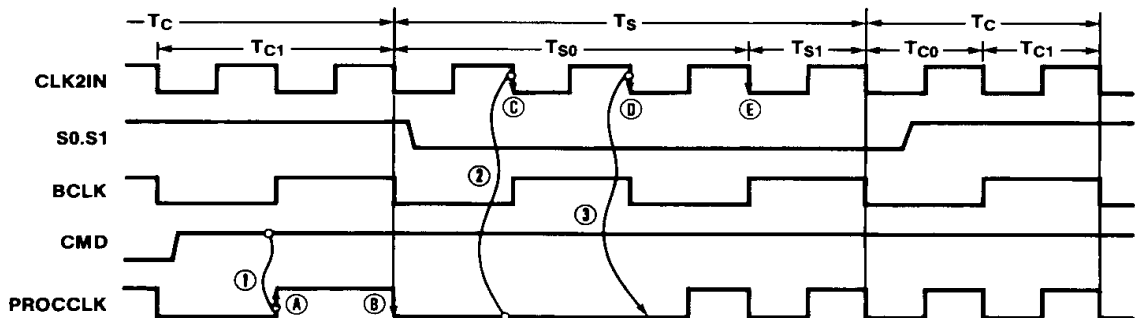


Figure 1.4 Sequence Diagram for Low to High Frequency Transition

denoted by sequence (3). This ensures a glitch free transition between the two clocks. It also does not violate the min and max 80286 CPU clock specifications. If BCLK is asynchronous with respect to CLK2IN, it is possible that sequence (2) could violate setup time requirements with respect to edge (C). In this case, edge (D) will register the state of PROCCLK as still being high in sequence (3). Hence, edge (E) samples PROCCLK to be low and edge (F) enables BCLK on the PROCCLK line. This case does not violate the min and max 80286 CPU clock specifications.

In Figure 1.4, the rising edge (A) of PROCCLK latches command inactive as denoted by sequence (1). Edge (B) disables BCLK on the PROCCLK line. In sequence (2), edge (C) of CLK2IN latches PROCCLK low. Edge (D) then enables CLK2IN on the PROCCLK line as denoted by sequence (3). If sequence (2) does not meet setup time requirements of edge (C), then the state of PROCCLK is sampled as being high in sequence (2). In this case, edge (D) samples PROCCLK low and edge (E) enables CLK2IN on the PROCCLK line. In this case also, PROCCLK does not violate the min and max 80286 CPU clock specifications.

1.2.3 CPU State Machine, Bus State Machine and Bus Arbitration

In order to extract maximum performance out of the 80286 on the system board, it is desirable to run the system board at the rated maximum CPU frequency. This frequency may be too fast for the slow AT bus. In order to overcome this problem, the 82C211 has two state machines: the CPU state machine which typically runs off CLK2IN, and the AT bus state machine which runs off BCLK. The two state machines maintain an asynchronous protocol under external mode operation.

CPU State Machine

Interface to the 80286 requires interpretation of the status lines S_0 , S_1 , M/IO during TS_0 and the synchronization and generation of $READY$ to the CPU upon completion of the requested operation. $IALE$ is issued in res-

ponse to the beginning of a new cycle in TS_1 by the 82C211. If AF_{16} is detected as being inactive at the end of the processor TS state, control is handed over to the AT bus state machine. The CPU state machine then waits for $READY$ to be active to terminate the current cycle. All local memory cycles are 16 bit cycles. If AF_{16} is asserted in response to a new CPU cycle and $READY$ is not returned to the 82C211 within 128 clocks, and $REG60H\langle 2 \rangle$ is enabled, then an NMI is generated to signal bus time-out, if NMI has been enabled.

AT Bus State Machine

The AT bus state machine gains control when AF_{16} is detected inactive by the CPU state machine. It uses BCLK which is twice the frequency of AT system clock SYSCCLK. When ATCLK is selected as the source for BCLK, it also performs the necessary synchronization of control and status signals between the AT bus and the processor. The 82C211 supports 8 and 16 bit transfers between the processor and 8 or 16 bit memory or I/O devices located on the AT bus. The action codes AC_0 , AC_1 qualified by $ACEN$ are used for bus sizing and 8, 16 bit bus conversions by the 82C215. They are discussed in section 1.2.4.

The AT bus cycle is initiated by asserting ALE in AT- TS_1 . On the falling edge of ALE , $MEMCS_{16}$ is sampled for a memory cycle to determine the bus size. It then enters the command cycle AT-TC and provides the sequencing and timing signals for the AT bus cycle. For an I/O cycle, $IOCS_{16}$ is sampled in the middle of the processor TC state. These control signals emulate the lower speed AT bus signals. The command cycle is terminated when $IOCHRDY$ is active on the AT bus and all programmed wait states have been executed.

It is possible to provide software selectable wait states and command delays to the AT state machine. Providing command delays causes the commands ($XMEMR$, $XMEMW$, $XIOR$ or $XIOW$) to be delayed from going active in BCLK steps. Providing wait states causes $READY$ to be delayed to the CPU in steps of the AT command cycles (AT-TC). The defaults and settings are discussed in section 1.4.

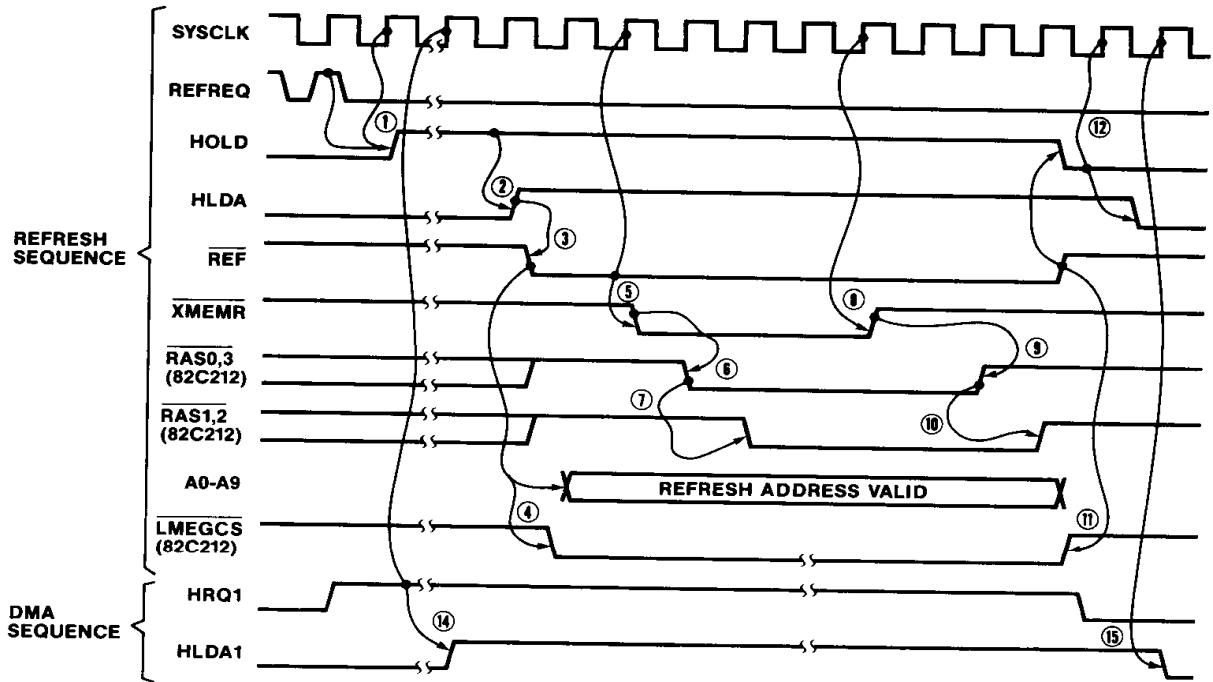


Figure 1.5 Refresh/DMA Sequence

Bus Arbitration

The 82C211 controls all bus activity and provides arbitration between the CPU, DMA/Master devices, and DRAM refresh logic. It handles HRQ and REFREQ by generating HOLD request to the CPU and arbitrating among these requests in a non-preemptive manner. The CPU relinquishes the bus by issuing HLDA. The 82C211 responds by issuing REF or HLDA1 depending on the requesting device. During a refresh cycle, the refresh logic has control of the bus until REF goes inactive. XMEMR is asserted low during a refresh cycle and the refresh address is provided on the A0-A9 address lines by the 82C211 to be used by the 82C212 memory controller. During a DMA cycle, the DMA controller has control of the bus until HRQ goes inactive. The 82C211 puts out the action codes for bus sizing. ALE, EALE and ACEN are active during DMA cycle.

Figure 1.5 is a sequence diagram for Refresh/DMA cycles. Upon receiving a refresh request

(REFREQ) it is internally latched by the 82C211. On the first rising edge of SYSCLK, HOLD is output to the processor in sequence 1. Depending on the current activity of the processor, a hold acknowledge (HLDA) is issued by the processor in sequence 2, after a DMA latency time. The 82C211 responds with REF active in sequence 3. LMEGCS from the 82C212 goes active in sequence 4. XMEMR is asserted low on the second rising edge of SYSCLK after REF is low in sequence 5. The 82C211 pulls all its RAS lines (RAS0-RAS3) high when REF goes low. The RAS lines go active in sequences 6 and 7 when the refresh address is active on the A0-A9 lines of the 82C211. The 82C212 uses the A0-A9 lines to generate the refresh address on the MA0-MA9 address lines. XMEMR goes inactive in sequence 8 followed by the RAS lines going inactive in sequences 9, 10. REF, LMEGCS and HOLD go inactive in sequence 11. Control is transferred to the CPU after HLDA goes inactive in sequence 12.

If a DMA device requests control of the bus,

the 82C211 receives HRQ1 active. After a DMA latency time, the CPU relinquishes the bus to the requesting device by issuing HLDA1 in sequence 14. HLDA1 is active as long as HRQ1 is active. Once the DMA device deasserts HRQ1, HLDA1 is deasserted by the 82C211 in sequence 15, to return control to the processor.

1.2.4 Action Codes Generation Logic

The AT state machine performs data conversion for CPU accesses to devices not on the CPU or Memory Bus. The AT bus conversions are performed for 16 to 8 bit read or write operations. Sixteen bit transfers to/from the CPU are broken into smaller 8 bit AT bus or peripheral bus reads or writes. The action codes are generated as shown in Table 1.1 to control the buffers in the 82C215. The action codes are in response to signals MEMCS16, IOCS16.

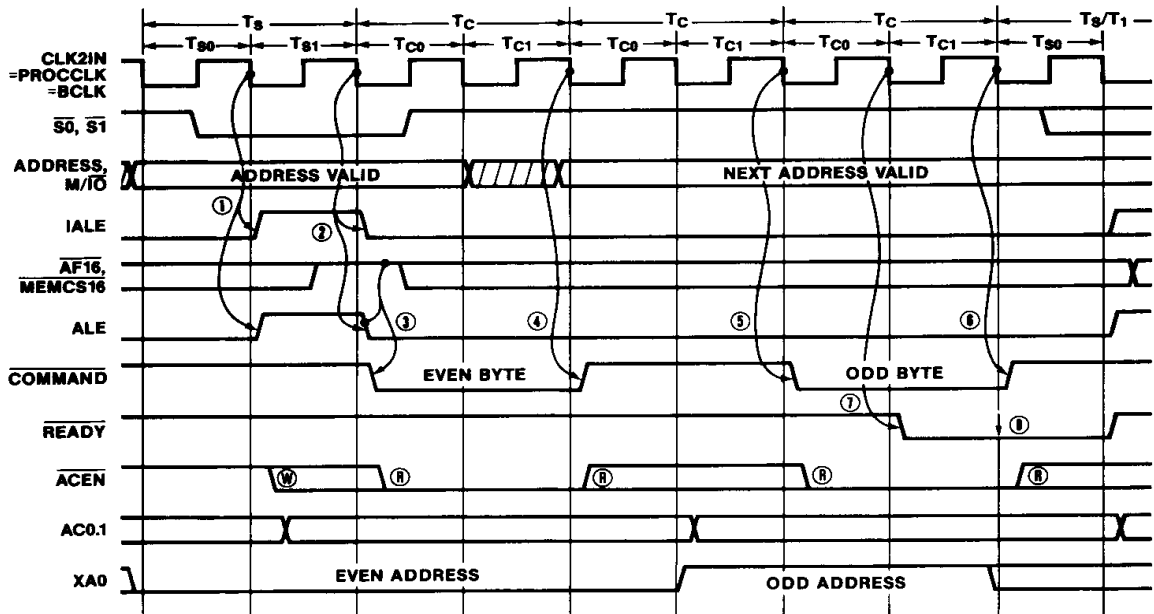
Table 1.1

Action Codes Enable (ACEN) Generation

Operation	ACEN
DMA/MASTER	0
CPU (local)	1
CPU (AT bus)	0 for write 0 qualified by command for read and interrupt acknowledge cycles
REFRESH	1 qualified by REF

AT-Bus CPU Cycles HLDA1 = 0

AC	Operation
00	16 bit write and 8 bit write (low byte)
01	16 bit read and 8 bit read (low byte)
10	8 bit write (high byte)
11	8 bit read (high byte)



NOTE: W.S. = WAIT STATUS, C.D. = COMMAND DELAYS, R = READ CYCLE, W = WRITE CYCLE.

Figure 1.6 Quick Mode Bus Conversion Cycle (0WS, 0CD)

DMA/MASTER Cycles, HLDA1 = 1

AC	Operation
00	MD bus tri-stated from the 82C215 for 16 bit and 8 (low byte) read/write operations
01	Reserved
10	High memory write MD0-7 to MD8-15
11	High memory read MD8-15 to MD0-7

Figure 1.6 shows a sequence diagram for a data conversion cycle in Quick mode with zero wait states (0 W.S.) and zero command delays (0 C.D.). Quick mode is discussed in section 1.3.2. In Quick mode ALE is issued on the AT bus as shown in sequences 1 and 2. MEMCS16 from an external device is sampled high by the 82C211 in sequence 3, initiating a bus conversion cycle. The first command also goes active in sequence 3 for the first byte operation and is terminated in sequence 4. In order to provide sufficient back to back time between the two 8 bit cycles, the second byte command is issued two PROCCLKs later in sequence 5 and is terminated in sequence 6. No second ALE is issued for the second byte operation since only address line XA0 changes from zero to one. READY is asserted low in sequence 7 and is sampled low by the processor in sequence 8, to terminate the current cycle. ACEN and AC0, AC1 are issued by the 82C211 for bus conversion as shown.

1.2.5 Port B and NMI generation logic

The 82C211 provides access to Port B defined for the PC/AT as shown in Figure 1.7.

IO ADDR	7	6	5	4	3	2	1	0	
61H	PCK	CHK	T20	RFD	EIC	EPR	SPK	T2G	PORT B

Figure 1.7 Port B

Bits	Read/Write	Function
7	R	PCK-System memory parity check
6	R	CHK-I/O channel check
5	R	T20-Timer 2 Out
4	R	RFD-Refresh Detect
3	R/W	EIC-Enable I/O channel check
2	R/W	ERP-Enable system memory parity check
1	R/W	SPK-Speaker Data
0	R/W	T2G-Timer 2 Gate (Speaker)

Table 1.2 Port B register definition

The NMI sub-module performs the latching and enabling of I/O and parity error conditions, which will generate a non-maskable interrupt to the CPU if NMI is enabled. Reading Port B will indicate the source of the error condition (IOCK and PCHK). Enabling and disabling of NMI is accomplished by writing to I/O address 070H. On the rising edge of XIOW, NMI will be enabled if data bit 7 (XD7) is equal to 0 and will be disabled if XD7 is equal to 1.

Numeric Coprocessor Interface

Incorporated in the 82C211 is the circuitry to interface an 80287 Numeric Coprocessor to 80286. The circuitry handles the decoding required for selecting and resetting the Numeric Coprocessor, handling NPBUSY and ERROR signals from the 80287 to the CPU, and generating interrupt signals for error handling.

The NPCS signal is active for I/O addresses 0F8H-0FFH, used to access the internal registers of the 80287. It is also active for I/O addresses 070H-NMI mask register, 0F0H-Clear Numeric Coprocessor BUSY signal, and 0F1H-Clear the Numerical Coprocessor and Numerical Coprocessor BUSY signal. While executing a task, the 80287 issues an NPBUSY

signal to the 82C211. Under normal operation, it is passed out to the CPU as **BUSY**. If during this busy period, a numeric coprocessor error occurs, **ERROR** input to the 82C211 becomes active, resulting in latching of the **BUSY*** output and assertion of **NPINT**. Both signals stay active until cleared by an I/O write cycle to address 0F0H or 0F1H. A system reset clears both **NPINT** and **BUSY** latches in the 82C211. The 80287 is reset through the **NPRESET** output, which can be activated by a system reset or by performing a write operation to I/O port 0F1H.

1.3 Modes of Operation of the 82C211

The 82C211 has 4 modes of operation for different CPU and AT bus clock selections:

- Normal mode
- Quick mode
- Delayed mode
- External mode

1.3.1 Normal mode

This mode is enabled by default (without writing to the internal registers of the 82C211). Under Normal mode:

PROCCLK = CLK2IN
 BCLK = CLK2IN/2
 SYSCLK = CLK2IN/4

Since the CPU state machine clock and the AT bus state machine clock are derived from CLK2IN, this is a synchronous mode. **ALE** and commands (**XMEMR**, **XMEMW**, **XIOR**, **XIOW**) are issued only for AT bus cycles and not for local cycles. If activated by default, I/O cycles will have one command delay, 8 bit AT memory cycles will have 4 wait states, 16 bit AT memory cycles will have 1 wait state.

Figure 1.8 shows the sequence diagram of a Normal mode local cycle followed by an AT bus cycle with zero wait states (0 W.S.) and

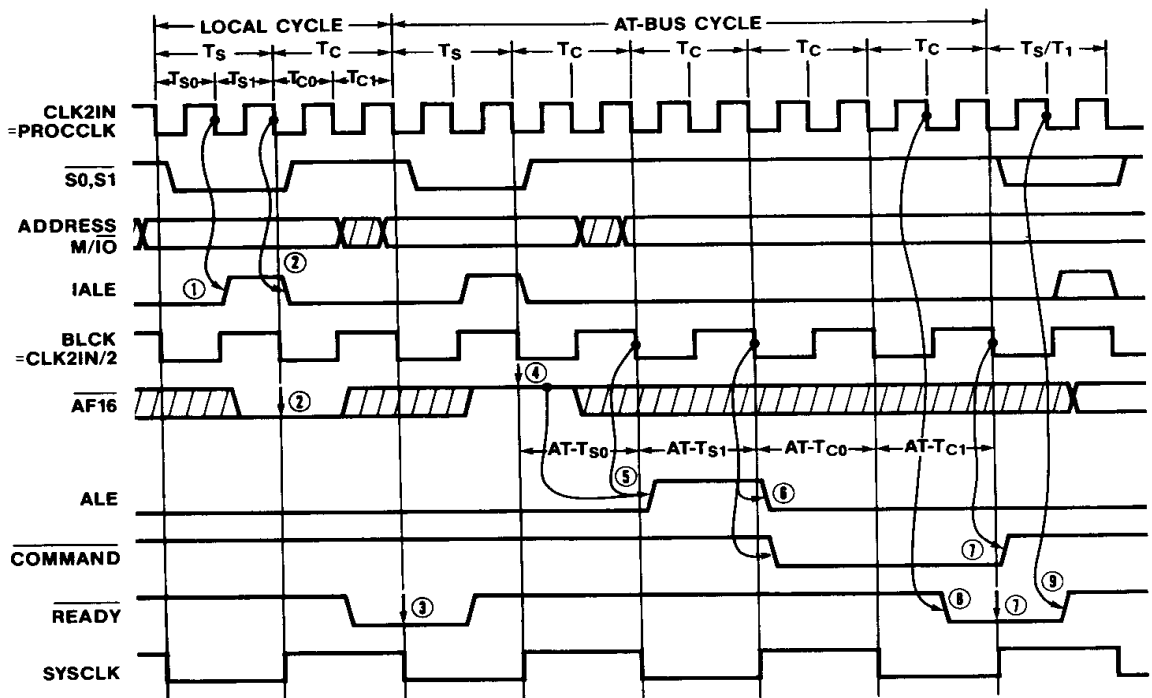
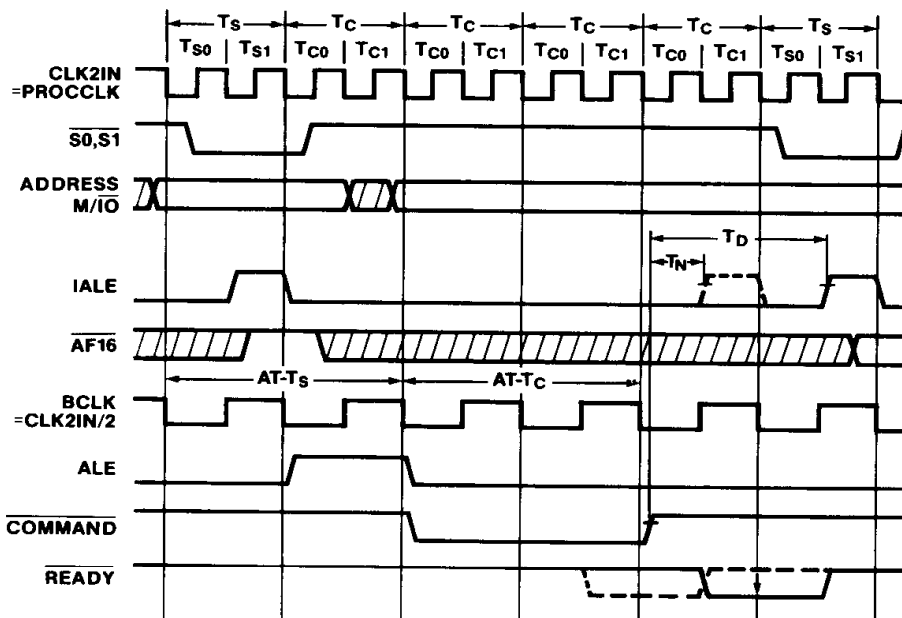


Figure 1.8 Normal Mode Local Cycle Followed by AT Bus Cycle (0WS, 0CD)



NOTE: T_D = DELAYED HOLD TIME, T_N = NORMAL HOLD TIME.

Figure 1.9 Normal Mode AT Bus Cycle with Additional Hold Time (0WS, 0CD)

zero command delays (0 C.D.). In sequences 1 and 2, IALE is generated from CLK2IN. AF16 is sampled to be low in sequence 2. ALE and AT bus commands (XIOR, XIOU, XMEMR, MEMW) are not generated since it is a local cycle. For a zero wait state cycle, ready is sampled low by the 80286 CPU in sequence 3 and the cycle is terminated. For the AT bus cycle, AF16 is sampled high in sequence 4. Control is transferred to the AT bus state machine. BCLK then generates the AT bus states. ALE is generated in sequences 5 and 6. The AT bus command is generated in sequences 6 and 7, for zero command delays programmed in the 82C211. For a zero wait state cycle, ready is asserted low as shown in sequences 8 and 9, to be sampled by the CPU in sequence 7. This terminates the AT bus cycle.

On the AT bus, certain slow peripherals require between 50 to 60 nanoseconds between command going inactive to the next ALE going active, to provide sufficient data recovery time. The sequence diagram in Figure

1.9 shows a Normal mode AT bus cycle with additional hold time. The dotted IALE signal would have been valid, if the additional hold time register had not been enabled in RA1<7>. Instead, IALE is delayed by one T_C state of the processor by asserting READY one T_C cycle later. The 82C212 provides an extended DLE to the 82C215 in this mode, so that data is available to the CPU during write cycles. If this mode was not invoked, then READY would have been asserted earlier as shown by the dotted line. In Delayed mode, the 82C211 provides an extended data hold time. This additional hold time can only be programmed in the Normal mode.

1.3.2 Quick mode

This mode is also a synchronous mode and is enabled by writing a zero to REG61<6> and the following clock selections have been made:

PROCCLK = BCLK = CLK2IN
 SYSCLK = CLK2IN/2

In Quick mode, an ALE signal is generated

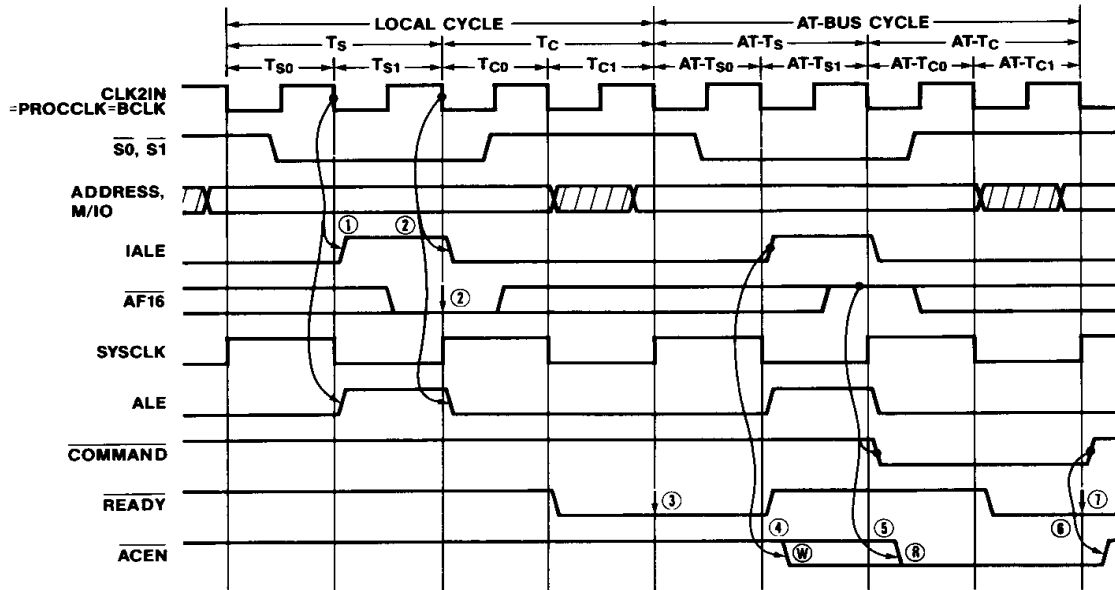


Figure 1.10 Quick Mode Local Cycle Followed by AT Bus Cycle (0WS, 0CD)

on the AT bus for both AT bus and local bus cycles. However, the commands (\overline{XMEMR} , \overline{XMEMW} , \overline{XIOR} , \overline{XIOW}) are not issued for local bus cycles.

The sequence diagram for a Quick mode local cycle followed by an AT bus cycle is shown in Figure 1.10. In this mode, both IALE and ALE are generated in sequences 1 and 2 for the local cycle. Hence, an ALE is issued on the AT bus for AT or non-AT bus cycles. The local cycle is terminated when READY is sampled low by the 80286 in sequence 3. For the AT bus cycle, the command is issued after $\overline{AF16}$ is sampled high in sequence 5. For write cycles, \overline{ACEN} is activated in sequence 4. For read cycles, \overline{ACEN} is activated in sequence 5. If the next cycle is not an AT bus write cycle, then \overline{ACEN} is negated in sequence 6. \overline{READY} is sampled low by the 80286 in sequence 6, to terminate the cycle. As seen in Figure 1.10, the AT bus states coincide with the CPU states for AT bus cycles. Hence, Quick mode is performance efficient when switching between local and AT bus cycles. This mode is useful for high speed add-on cards such as Lazer Printer interface cards.

1.3.3 Delayed mode

This mode is another synchronous mode and is enabled when Quick mode is disabled and the following clock selections have been chosen made:

PROCCLK = CLK2IN
 BCLK = CLK2IN
 SYSCLK = CLK2IN/2

In Delayed mode, ALE and commands are issued only for AT bus cycles like in the Normal mode, except that BCLK = CLK2IN. ALE and commands are not issued for local cycles. Figure 1.11 shows a Delayed mode AT bus cycle. IALE is generated in sequences 1 and 2. ALE is asserted in sequence 3 after sampling $\overline{AF16}$ high and it is deasserted in sequence 4. Hence the AT bus states, though synchronous, are delayed with respect to the processor states. Figure 1.11 is an example with two command delays and three wait states. The dotted lines A and B show command going active for 0 and 1 command delays. Sequence 5 shows command going active for programmed 2 command delays.

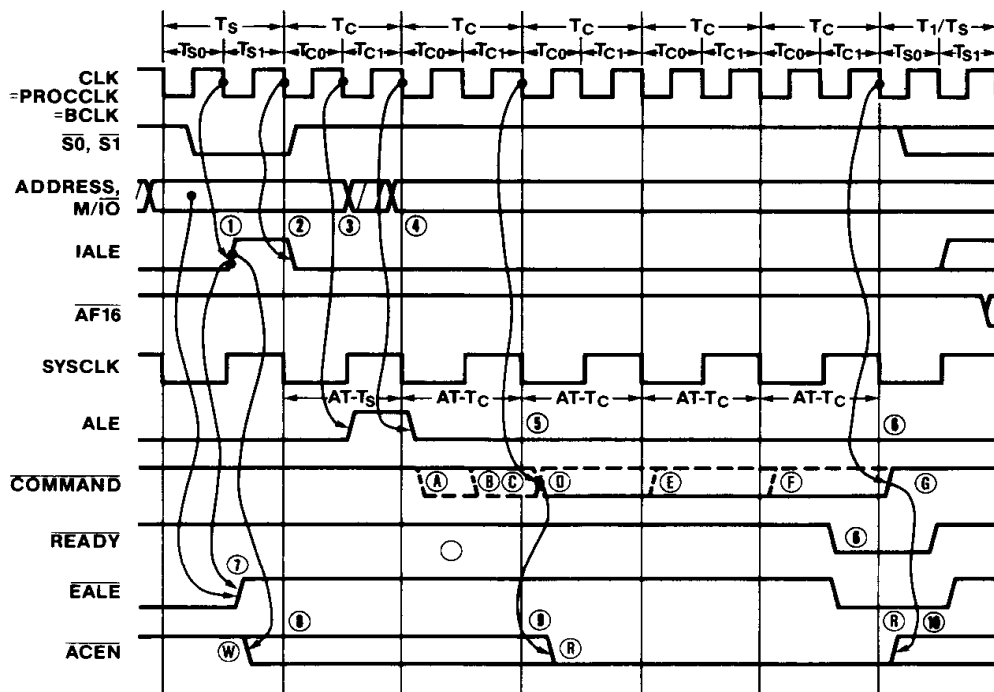


Figure 1.11 Delayed Mode AT Bus Cycle (3WS, 2CD)

Dotted lines D, E, F show command going inactive for 0, 1, 2 wait states. Sequence 6 shows command going inactive for programmed 3 wait states. **READY** is sampled by the 80286 in sequence 6 to terminate the current cycle. Since the AT bus states are delayed with respect to the processor states, the Local Address lines LA17-LA23 (typically unlatched) are not valid when **ALE** is active. In order to have the LA17-LA23 lines valid when **ALE** is active, they are latched by **EALE** as shown in sequence 7. Sequences 8, 9 show when **ACEN** is asserted for AT bus write (W) and read (R) cycles. **ACEN** is deasserted in sequence 10. This mode is useful for slow peripheral AT add-on cards.

1.3.4 External mode

This is an asynchronous mode and is enabled when **ATCLK** is selected as the source for **BCLK**. The following clock selections are required in this mode:

PROCCLK = CLK2IN
 BCLK = ATCLK
 SYSCLK = ATCLK/2

Since **ATCLK** is asynchronous to **CLK2IN**, the CPU state machine runs asynchronous to the AT bus state machine. **ALE** and commands (**XMEMR**, **XMEMW**, **XIOR**, **XIOW**) are issued only for AT bus cycles. These signals are inactive for local cycles. Figure 1.12 shows a sequence diagram for an External mode AT bus cycle. **AF16** is sampled high in sequence 2 and is latched internally, using **CLK2IN**. The asynchronous **BCLK** samples this latched state on the next rising edge of **BCLK**. In the example shown, edge A samples the latched **AF16** signal (internal) high. This causes the AT state machine to issue an **ALE** in sequences 3 and 4. For a zero command delay, zero wait states cycle, the command is issued on the AT bus in sequences 4 and 6, synchronized with **BCLK**. For write cycles, **ACEN** is asserted in sequence 1 and for read cycles, it is asserted in sequence 5. **ACEN** is deasserted in sequence 7. The command inactive state is sampled by **CLK2IN** on every rising edge. In this case, edge D of **CLK2IN** samples command high (sequence 8). It is followed by the assertion of **READY** in sequence 9, syn-

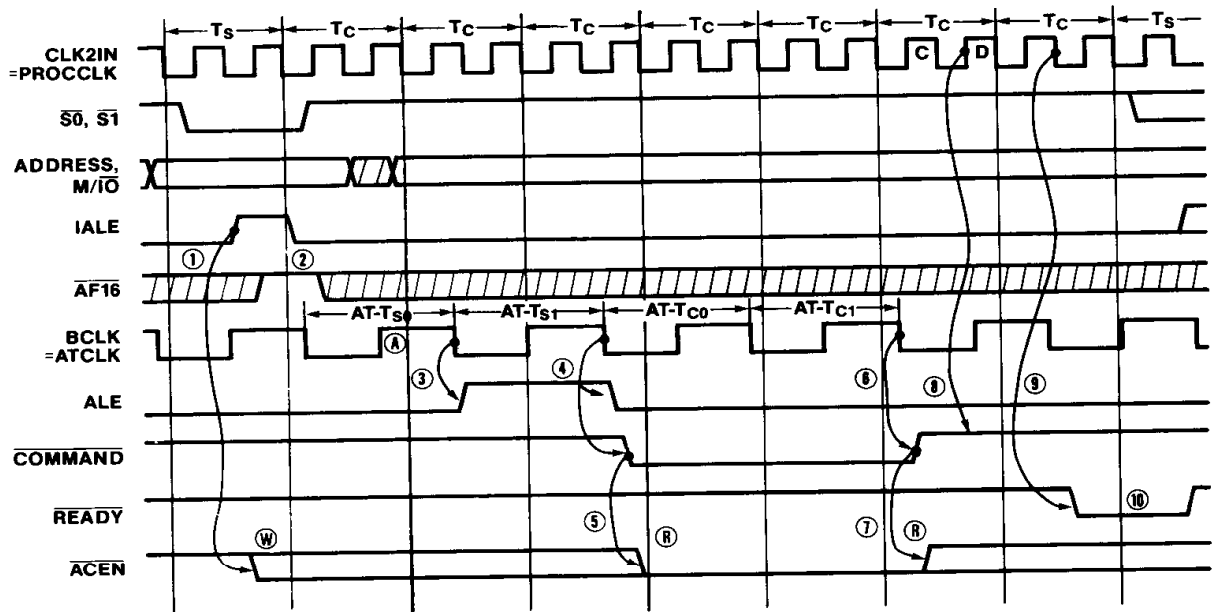


Figure 1.12 External Mode AT Bus Cycle (0WS, 0CD)

chronized with CLK2IN. The CPU samples READY low in sequence 10 and terminates the current cycle.

1.4 Configuration Registers

There are three bytes of configuration registers in the 82C211; RA0, RA1 and RA2. An indexing scheme is used to reduce the I/O ports required to access all the registers required for the NEAT CHIPSet. Port 22H is used as an indexing register and Port 23H is used as the data register. The index value is placed in port 22H to access a particular register and the data to be read from or written to that register is located in port 23H. Every access to port 23H must be preceded by a write of the index value to port 22H even if the same register data is being accessed again. All reserved bits are set to zero by

default and when written to, must be set to zero. Table 1.3 lists the three registers:

Table 1.3

Register Number	Register Name	Index
RA0	PROCCLK Selector	60H
RA1	Command Delay	61H
RA2	Wait State/ BCLK Selector	62H

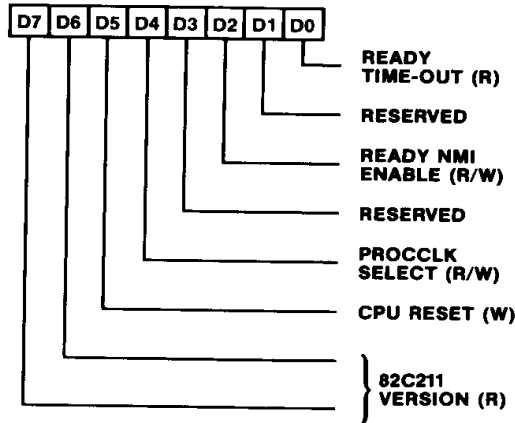
1.4.1 Register Description

PROCCLK Register RA0

Index register port: 22H

Data register port: 23H

Index: 60H



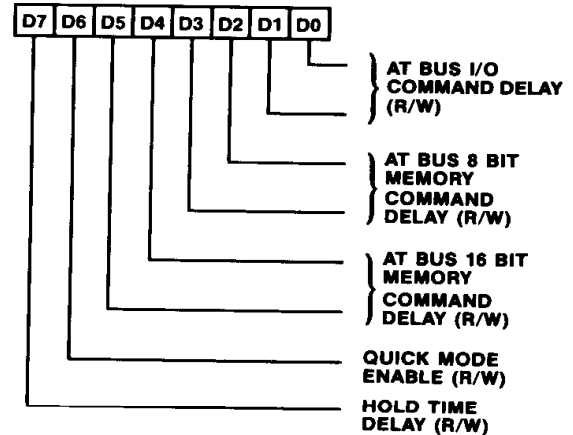
Bits	Function
7, 6	82C211 revision number. 00 is the initial number.
5	Alternate CPU reset. A low to high transition in this bit activates a CPU reset. Once active, it remains active for 16 PROCCLK cycles and then goes low.
4	Processor clock select is by default set to zero and selects PROCCLK = CLK2IN. If high, it selects PROCCLK = BCLK.
3	Reserved.*
2	Local bus READY timeout NMI enable. A one enables the NMI and a zero disables it. Default is 0
1	Reserved.*
0	Local bus READY timeout. A one indicates that READY timeout has occurred 128 PROCCLK cycles after AF16 has been asserted. A zero indicates that READY time out has not occurred.

Command Delay Register RA1

Index register port: 22H

Data register port: 23H

Index: 61H



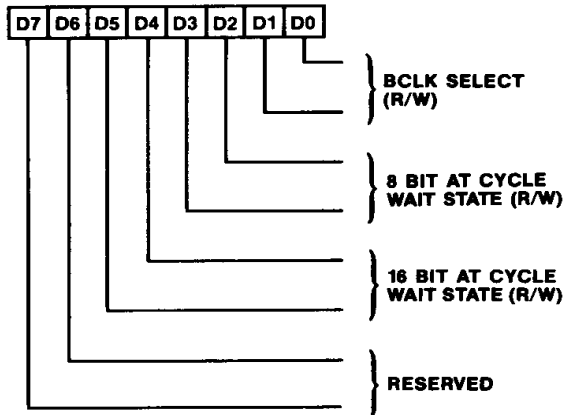
Bits	Function
1, 0	AT Bus I/O cycle command delay. Specifies between 0 to 3 BCLK cycle command delays for AT I/O cycles. Default is 1.
3, 2	AT Bus 8 bit memory command delay. Specifies between 0 to 3 BCLK cycle command delays for 8 bit AT memory cycles. Default is 1.
5, 4	AT Bus 16 bit memory command delay. Specifies between 0 and 3 BCLK cycle command delays for 16 bit AT memory cycles. Default is 0
6	Quick mode enable. A zero enables Quick mode and a one disables it. Default is 1.
7	Address hold time delay. A one enables extra address bus hold time and a zero disables it. Default is 0.

Wait States Register RA2

Index register port: 22H

Data register port: 23H

Index: 62H



Bits	Function
1, 0	Bus clock (BCLK) source select. Default is 00.
00	BCLK = CLK2IN/2
01	BCLK = CLK2IN
10	BCLK = ATCLK
11	Reserved
3, 2	8 bit AT cycle wait state generation. Default is 5.
00	2 wait states
01	3 wait states
10	4 wait states
11	5 wait states
5, 4	16 bit AT cycle wait state generation. Default is 3.
00	0 wait states
01	1 wait state
10	2 wait states
11	3 wait states
7, 6	Reserved.*

*The reserved bits are recommended to be initialized to 1.

1.5 Absolute Maximum Ratings

Parameter	Symbol	Min.	Max.	Units
Supply Voltage	V_{CC}	—	7.0	V
Input Voltage	V_I	-0.5	5.5	V
Output Voltage	V_O	-0.5	5.5	V
Operating Temperature	T_{OP}	-25°	85°	C
Storage Temperature	T_{STG}	-40°	125°	C

NOTE: Permanent device damage may occur if Absolute Maximum Ratings are exceeded. Functional operation should be restricted to the conditions described under Operating Conditions.

1.6 82C211 Operating Conditions

Parameter	Symbol	Min.	Max.	Units
Supply Voltage	V_{CC}	4.75	5.25	V
Ambient Temperature	T_A	0°	70°	C

1.7 82C211 DC Characteristics

Parameter	Symbol	Min.	Max.	Units
Input Low Voltage	V_{IL}	—	0.8	V
Input High Voltage	V_{IH}	2.0	—	V
Output Low Voltage $I_{OL} = 4\text{mA}$	V_{OL}	—	0.45	V
Output High Voltage $I_{OH} = -4\text{mA}$	V_{OH}	2.4	—	V
Input Current $0 < V_{IN} < V_{CC}$	I_{IL}	—	± 10	μA
Power Supply Current @ 16MHz	I_{CC}	—	50	mA
Output High-Z Leakage Current $0.45 < V_{OUT} < V_{CC}$	I_{OZ1}		± 10	μA
PROCCLK Output Low Voltage @ $I_{OL} = 5\text{mA}$	V_{OLC}	—	0.45	V
PROCCLK Output High Voltage @ $I_{OH} = -1\text{mA}$	V_{OHC}	4.0	—	V
Standby Power Supply Current	I_{CCSB}	—	1.5	mA

1.8 82C211-12, 82C211-16 AC Characteristics

($T_A = 0^\circ\text{C}$ to 70°C , $V_{CC} = 5\text{V} \pm 5\%$)

Sym	Description	Min.	Typ.	Max.	Units
t1	ALE active delay from SYSCLK \uparrow	-1		6 (10)	ns
t2	ALE inactive delay from SYSCLK \uparrow	-1		6 (10)	ns
t3	COMMAND active delay from SYSCLK \uparrow	0		8	ns
t4	COMMAND inactive delay from SYSCLK \uparrow	0		6	ns
t5	$\overline{\text{EALE}}$ active delay from SYSCLK \uparrow	0		10	ns
t6	$\overline{\text{MEMCS16}}$ set-up time to SYSCLK \uparrow	10			ns
t7	$\overline{\text{MEMCS16}}$ hold time to SYSCLK \uparrow	4			ns
t8	$\overline{\text{IOCS16}}$ set-up time to SYSCLK \uparrow	10			ns
t9	$\overline{\text{IOCS16}}$ hold time to SYSCLK \uparrow	10			ns
t10	$\overline{\text{OWS}}$ set-up time to SYSCLK \uparrow	9			ns
t11	$\overline{\text{OWS}}$ hold time to SYSCLK \uparrow	4			ns
t12	IOCHRDY set-up time to SYSCLK \uparrow	11			ns
t13	IOCHRDY hold time to SYSCLK \uparrow	4			ns
t14	IALE active delay from PROCCLK \uparrow	1		10	ns
t15	IALE inactive delay from PROCCLK \uparrow	1		11 (16)	ns
t16	$\overline{\text{AF16}}$ set-up time to PROCCLK \uparrow	15(19)			ns
t17	$\overline{\text{AF16}}$ hold time to PROCCLK \uparrow	11(13)			ns
t18	$\overline{\text{READY}}$ input set-up time to PROCCLK \uparrow	11			ns
t19	$\overline{\text{READY}}$ input hold time PROCCLK \uparrow	8			ns
t20	RESET3 active delay from PROCCLK \uparrow	2		12	ns
t21	RESET3 inactive delay from PROCCLK \uparrow	2		16	ns
t22	RESET4 active delay from PROCCLK \uparrow	0		8	ns
t23	RESET4 inactive delay from PROCCLK \uparrow	1		16	ns
t24	SDIR<1:0> active delay from SYSCLK \uparrow	3		11	ns
t25	SDIR<1:0> inactive delay from SYSCLK \uparrow	1		10	ns
t26	$\overline{\text{ACEN}}$ active delay from SYSCLK \uparrow	0		7	ns
t27	$\overline{\text{ACEN}}$ inactive delay from SYSCLK \uparrow	0		6	ns
t32	AC0 active delay from PROCCLK \uparrow	6		17	ns
t33	AC0 inactive delay from PROCCLK \uparrow	6		18	ns
t34	AC1 active delay from PROCCLK \uparrow	7		18	ns

1.8 82C211-12, 82C211-16 AC Characteristics (Continued)

($T_A = 0^\circ\text{C}$ to 70°C , $V_{CC} = 5V \pm 5\%$)

Sym	Description	Min.	Typ.	Max.	Units
t35	AC1 active delay from PROCCLK \dagger	7		18	ns
t38	Hold active delay from SYSCLK \dagger	0		6	ns
t39	Hold inactive delay from SYSCLK \dagger	0		6	ns
t40	$\overline{\text{REF}}$ delay from HLDA	3		14	ns
t43	$\overline{\text{REF}}$ inactive delay from SYSCLK \dagger	0		6	ns
t44	XMEMR active delay from SYSCLK \dagger	1		9	ns
t45	XMEMR inactive delay from SYSCLK \dagger	0		5	ns
t46	HRQ1 set-up to SYSCLK \dagger	10			ns
t47	HRQ1 hold time to SYSCLK \dagger	4			ns
t49	HLDA1 active delay from HLDA \dagger	8		17	ns
t51	HLDA1 inactive delay from HLDA \dagger	12		20	ns
t52	$\overline{\text{NPCS}}$ active delay from PROCCLK \dagger	11		21	ns
t53	Overlap of $\overline{\text{NPBUSY}}$ & $\overline{\text{ERROR}}$ (both low)	8			
t54	NPINT delay from $\overline{\text{NPBUSY}}$, $\overline{\text{ERROR}}$ low	7		16	ns
t55	NPINT inactive delay from $\overline{\text{ERROR}}$ \dagger	3		11	ns
t56	$\overline{\text{NPBUSY}}$ active pulse width	13			
t57	$\overline{\text{ERROR}}$ hold time with respect to $\overline{\text{NPBUSY}}$ \dagger	0			
t58	$\overline{\text{ERROR}}$ set up time to $\overline{\text{NPBUSY}}$ \dagger	3			
t59	$\overline{\text{ERROR}}$ min low pulse	8			
t60	$\overline{\text{BUSY}}$ active delay from $\overline{\text{NPBUSY}}$ \dagger	8		18	ns
t61	$\overline{\text{BUSY}}$ inactive delay from $\overline{\text{NPBUSY}}$ \dagger	8		15	ns
t62	$\overline{\text{BUSY}}$ delay from $\overline{\text{IOW}}$	2		12	ns
t63	NPRST active delay from $\overline{\text{IALE}}$	9		19	ns
t64	NPRST inactive delay from $\overline{\text{IALE}}$	4		15	ns

Note: Values inside () are 12 MHz timing.

For normal mode of operation, only one bank of DRAMs may be used. However, for the page/interleaved mode of operation, RAM bank pairs must be used.

Shadow RAM Feature

For efficient execution of BIOS, it is preferable to execute BIOS code through RAM rather than through slower EPROMs. The 82C212 provides the shadow RAM feature which if enabled allows the BIOS code to be executed from system RAM resident at the same physical address as the BIOS EPROM. The software should transfer code stored in the BIOS EPROMs to the system RAM, before enabling the shadow RAM feature. This feature significantly improves the performance in BIOS-call intensive applications. Performance improvements as high as 300 to 400% have been observed in benchmark tests on the shadow RAM. The shadow RAM feature is invoked by enabling the corresponding bits in the ROM enable register and the RAM mapping register.

If more than 1 Mbyte of system RAM exists, it is mapped as shown in Figure 2.7, if the shadow RAM feature is not invoked. This means that RAM in the 640 Kbyte to 1 Mbyte area cannot be accessed. If the shadow RAM feature is used, then the RAM is mapped as

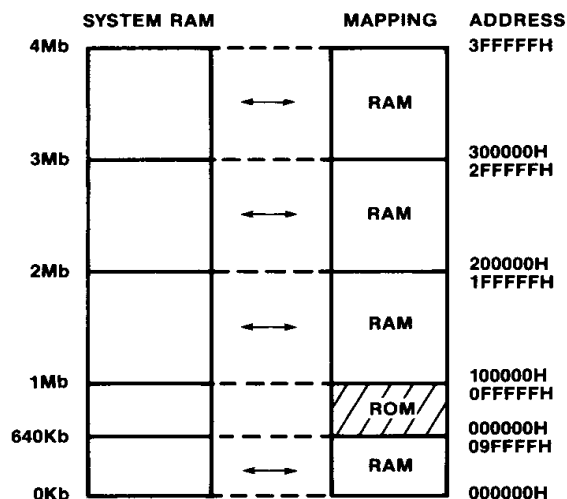


Figure 2.7 RAM/ROM Mapping Without Shadow RAM (More Than 1MB of RAM)

shown in Figure 2.8, overlapping or Shadowing the EPROM area. In both cases, for accesses beyond the 1 Mbyte address range, the processor is switched from real to protected mode from BIOS.

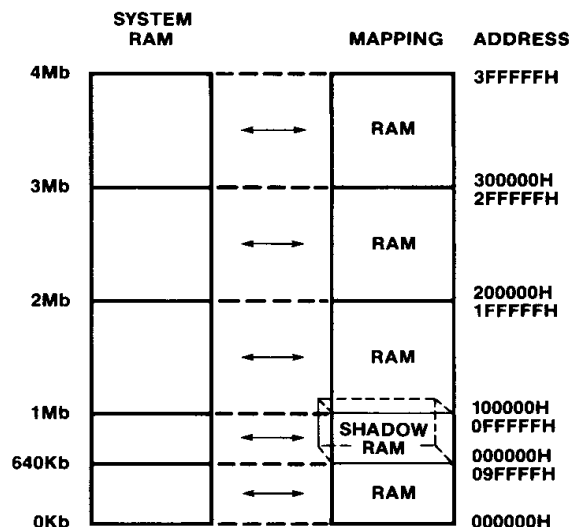


Figure 2.8 RAM Mapping with Shadow RAM (More Than 1MB of RAM)

EMS Address Translation Logic

Expanded Memory System or EMS is a memory mapping scheme used to map a 64 Kbyte block of memory in the EPROM area D0000H-DFFFFH to anywhere in the 1 Mbyte-8 Mbyte area. This 64 Kbyte memory block is segmented into four 16 Kbyte pages. Through a translation table, each 16 Kbyte segment can be mapped anywhere in the 1 Mbyte to 8 Mbyte area. Since the 82C212 uses the translation table in the EMS mode, address lines A14 to A22 are translated by the appropriate EMS mapping register. Hence, this scheme does not require switching between user and protected mode. Figure 2.9 shows the EMS organization with a possible translation scheme. It is possible for the 82C212 to map this 64 Kbyte block to anywhere in the 0 to 8 Mbyte area. However, it is desirable to map this block above the 1 Mbyte area in order to not use the RAM space in the 0 to 640 Kbyte area. Although the EMS scheme translates the 64 Kbyte block in the D0000H-DFFFFH

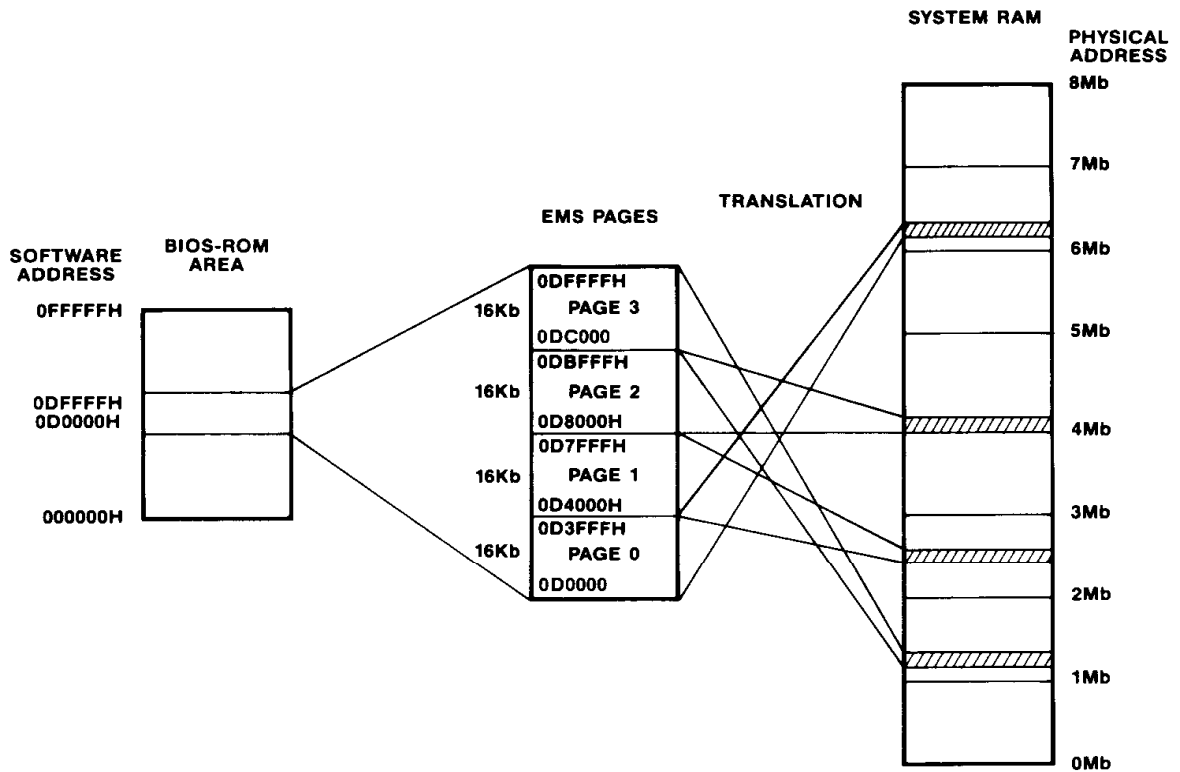


Figure 2.9 EMS Mapping

area, it is possible to select a 64 Kbyte block from any other area.

Refresh Logic

During a refresh cycle, the 82C211 puts out the refresh address on the A0-A9 address lines and asserts the $\overline{\text{REF}}$ signal low to the 82C212. The 82C212 uses these signals to generate the refresh address on the MA0-MA9 address lines, the $\overline{\text{RAS}}$ signals and $\overline{\text{LMEGCS}}$. Figure 1.5 is a sequence diagram for a refresh cycle. As seen, the 82C212 performs a staggered mode refresh to reduce the power supply noise generated during $\overline{\text{RAS}}$ switching. Prior to a refresh, all $\overline{\text{RAS}}$ lines are pulled high to ensure $\overline{\text{RAS}}$ precharge. Following this, $\overline{\text{RAS0}}$ and $\overline{\text{RAS3}}$ are asserted low.

$\overline{\text{RAS1}}$ and $\overline{\text{RAS2}}$ are staggered by one delay unit using an external delay line, with respect to $\overline{\text{RAS0}}$ and $\overline{\text{RAS3}}$. The $\overline{\text{RAS0-RAS3}}$, $\overline{\text{RAS1-RAS2}}$ bundling is provided so that staggering is effective for a minimal 2 bank or a full 4 bank configuration.

Memory Configurations

It is possible to use 1Mbit or 256K bit (and in one case, 64K bit) DRAMs for system memory in the NEAT CHIPSet™. Each memory bank can be implemented with eighteen 1 bit wide DRAMs or four 4 bit wide DRAMs with two 1 bit wide DRAMs. Possible configurations for onboard memory are listed in Table 2.1. Each bank is 16 bits wide plus two bits for parity.

Table 2.1

	DRAM Type				Total Memory	EMS Range
	Bank0	Bank1	Bank2	Bank3		
1	0	0	0	0	disable	0
2	256K	0	0	0	512Kb	0
3	1M	0	0	0	2Mb	1Mb to 2Mb
4	256K	64K	0	0	640Kb	0
5	256K	256K	0	0	1Mb	1Mb to 1.384Mb
6	1M	1M	0	0	4Mb	1Mb to 4Mb
7	256K	256K	256K	0	1.5Mb	1Mb to 1.5Mb
8	256K	256K	1M	0	3Mb	1Mb to 3Mb
9	1M	1M	1M	0	6Mb	1Mb to 6Mb
10	256K	64K	256K	256K	1.64Mb	1Mb to 1.64Mb
11	256K	256K	256K	256K	2Mb	1Mb to 2Mb
12	256K	64K	1M	1M	4.64Mb	1Mb to 4.64Mb
13	256K	256K	1M	1M	5Mb	1Mb to 5Mb
14	1M	1M	1M	1M	8Mb	1Mb to 8Mb

Page/interleaving is possible for only those combinations with similar pairs of DRAMs. In table 2.1, page/interleaving is possible with combinations 5, 6, 11, 13 and 14.

2.4 Clock Generation Logic

The 82C212 has an oscillator circuit which uses a 14.31818 MHz crystal to generate the OSC and OSC/12 clocks. The 1.19381 MHz OSC/12 clock is used internally to generate the RAS timeout clocks, one for each bank. RAS is deasserted for each bank when its RAS time out counter times out after about 10 microseconds.

2.5 Configuration Registers

There are twelve configuration and diagnostics registers in the 82C212, RB0-RB11. These are accessed through IO ports 22H and 23H normally found in the interrupt controller module of the 82C206 IPC. An indexing scheme is used to reduce the number of I/O addresses required to access all of the registers needed to configure and control the memory controller. Port 22H is used as an index register that points to the required data value accessed through port 23H. A write of the index value for the required data is performed to location 22H. This is then decoded and controls the multiplexers gating the appropriate register to the output bus. Every access to port 23H must be preceded by a write of the index value to port 22H even if the same data register is being accessed again. All bits marked as Reserved are set to zero by default and must be maintained that way during write operations. Table 2.2 lists these registers.

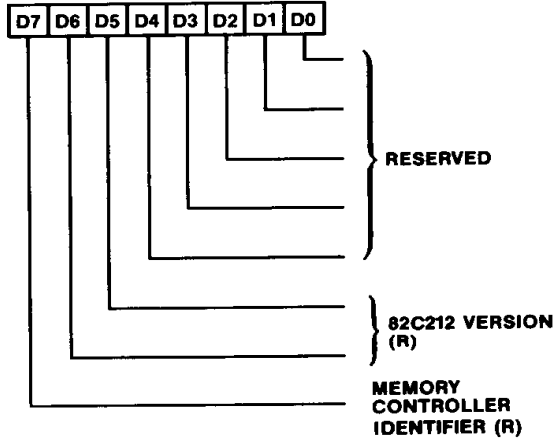
Table 2.2

Register Number	Register Name	Index
RB0	Version	64H
RB1	ROM Configuration	65H
RB2	Memory Enable-1	66H
RB3	Memory Enable-2	67H
RB4	Memory Enable-3	68H
RB5	Memory Enable-4	69H
RB6	Bank 0/1 Enable	6AH
RB7	DRAM Configuration	6BH
RB8	Bank 2/3 Enable	6CH
RB9	EMS Base Address	6DH
RB10	EMS Address Extension	6EH
RB11	Miscellaneous	6FH

2.5.1 Register Description

Version Register RB0

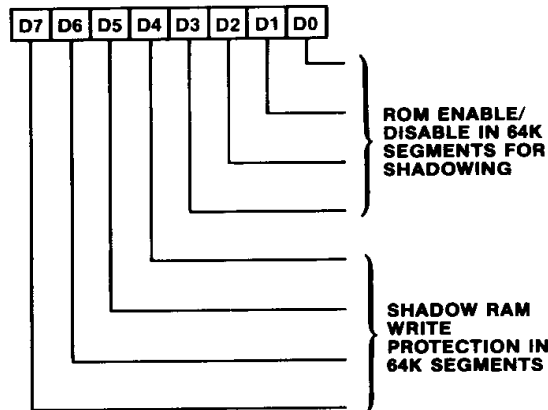
Index register port: 22H
 Data register port: 23H
 Index: 64H



Bits	Function
7	NEAT memory controller identifier. 0 = 82C212
6, 5	82C212 revision number. 00 = initial revision number
4-0	Reserved and default to 0*

ROM Configuration Register RB1

Index register port: 22H
 Data register port: 23H (R/W)
 Index: 65H



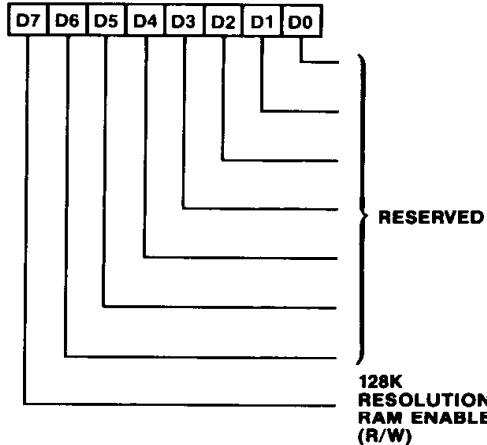
Bits	Function
0	ROM at F0000H-FFFFFFH (BIOS). Default = 0 = ROM enabled. ROMCS is generated.
1	ROM at E0000H-EFFFFFFH. Default = 1 = ROM disabled, Shadow RAM enabled. ROMCS is not generated unless bit is set to 0.
2	ROM at D0000H-DFFFFFFH. Default = 1 = ROM disabled, Shadow RAM enabled. ROMCS is not generated unless bit is set to 0.
3	ROM at C0000H-CFFFFFFH (EGA). Default = 1 = ROM disabled, Shadow RAM enabled. ROMCS is not generated unless bit is set to 0.
4	Shadow RAM at F0000H-FFFFFFH in Read/Write mode. 0 = Read/Write (default), 1 = Read only (Write protected).
5	Shadow RAM at E0000H-EFFFFFFH in Read/Write mode. 0 = Read/Write (default), 1 = Read only (Write protected).
6	Shadow RAM at D0000H-DFFFFFFH in Read/Write mode. 0 = Read/Write (default), 1 = Read only (Write protected).
7	Shadow RAM at C0000H-CFFFFFFH in Read/Write mode. 0 = Read/Write (default), 1 = Read only (Write protected).

Memory Enable-1 Register RB2

Index register port: 22H

Data register port: 23H

Index: 66H



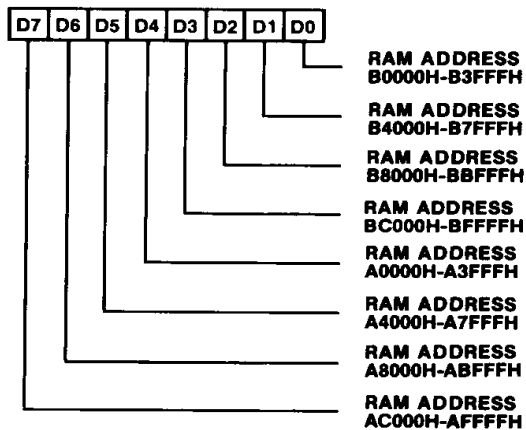
Bits	Function
0-6	Reserved and default to 0*
7	Address map RAM on system board in 80000H-9FFFFH area. 0 = Address is on the I/O channel (Default), 1 = Address is on the system board and is put out by the 82C212.

Memory Enable Register-2 RB3

Index register port: 22H

Data register port: 23H (R/W)

Index: 67H



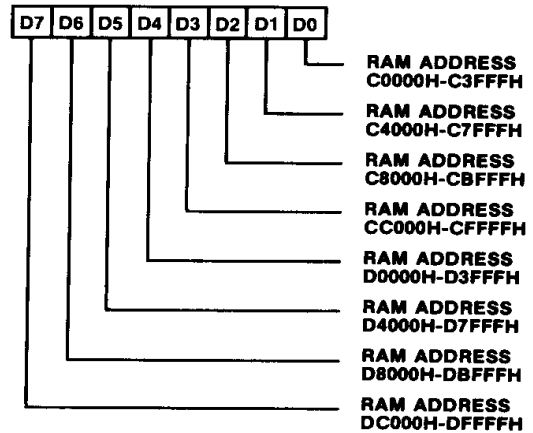
Bits	Function
0	Enable Shadow RAM in B0000H-B3FFFH area. Disable = 0 Enable = 1.
1	Enable Shadow RAM in B4000H-B7FFFH rea. Disable = 0 Enable = 1.
2	Enable Shadow RAM in B8000H-BBFFFH area. Disable = 0 Enable = 1.
3	Enable Shadow RAM in BC000H-BFFFFH area. Disable = 0 Enable = 1.
4	Enable Shadow RAM in A0000H-A3FFFH area. Disable = 0 Enable = 1.
5	Enable Shadow RAM in A4000H-A7FFFH area. Disable = 0 Enable = 1.
6	Enable Shadow RAM in A8000H-ABFFFH area. Disable = 0 Enable = 1.
7	Enable Shadow RAM in AC000H-AFFFFH area. Disable = 0 Enable = 1.

Memory Enable-3 Register RB4

Index register port: 22H

Data register port: 23H (R/W)

Index: 68H

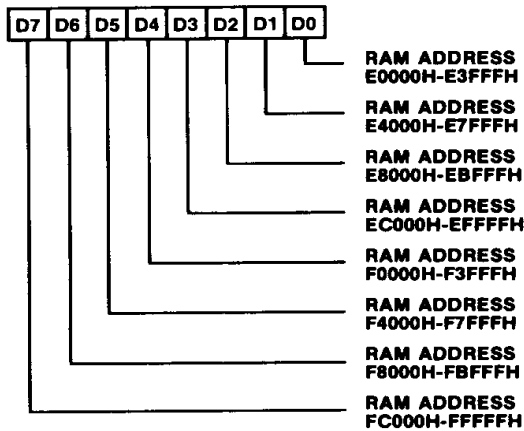


Bits	Function
0	Enable Shadow RAM in C0000H-C3FFFH area. Disable = 0 Enable = 1.
1	Enable Shadow RAM in C4000H-C7FFFH area. Disable = 0 Enable = 1.

2	Enable Shadow RAM in C8000H-CBFFFH area. Disable = 0 Enable = 1.
3	Enable Shadow RAM in CC000H-CFFFFH area. Disable = 0 Enable = 1.
4	Enable Shadow RAM in D0000H-D3FFFH area. Disable = 0 Enable = 1.
5	Enable Shadow RAM in D4000H-D7FFFH area. Disable = 0 Enable = 1.
6	Enable Shadow RAM in D8000H-DBFFFH area. Disable = 0 Enable = 1.
7	Enable Shadow RAM in DC000H-DFFFFH area. Disable = 0 Enable = 1.

Memory Enable-4 Register (RB5)

Index register port: 22H
Data register port: 23H (R/W)
Index: 69H

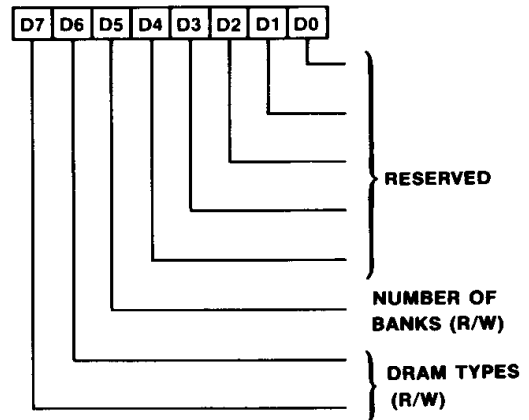


Bits	Function
0	Enable Shadow RAM in E0000H-E3FFFH area. Disable = 0 Enable = 1.
1	Enable Shadow RAM in E4000H-E7FFFH area. Disable = 0 Enable = 1.
2	Enable Shadow RAM in E8000H-EBFFFH area. Disable = 0 Enable = 1.
3	Enable Shadow RAM in EC000H-EFFFFH area. Disable = 0 Enable = 1.
4	Enable Shadow RAM in F0000H-F3FFFH area. Disable = 0 Enable = 1.

5	Enable Shadow RAM in F4000H-F7FFFH area. Disable = 0 Enable = 1.
6	Enable Shadow RAM in F8000H-FBFFFH area. Disable = 0 Enable = 1.
7	Enable Shadow RAM in FC000H-FFFFFH area. Disable = 0 Enable = 1.

Bank 0/1 Enable Register RB6

Index register port: 22H
Data register port: 23H
Index: 6AH

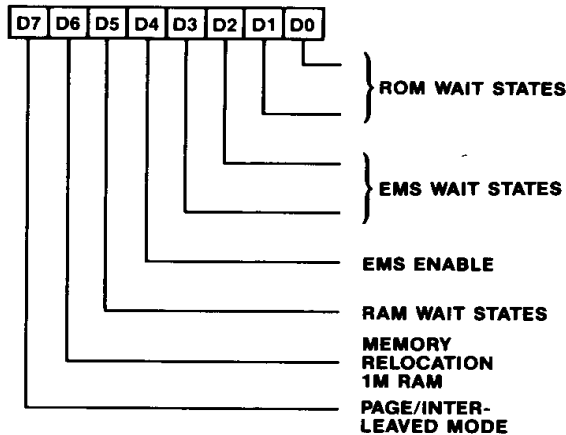


Bits	Function
0-4	Reserved and default to 0*
5	Number of RAM banks used. 0 = one bank, non-interleaved mode (Default), 1 = two banks
7, 6	These bits contain the information for the DRAM types used on the system board. POST/BIOS should use the DRAM configuration data stored in the CMOS RAM of the 82C206 IPC.

7	6	DRAM Types
0	0	Disabled
0	1	256K and 64K bit DRAMs used (for 640 Kbyte combination only)
1	0	256K bit DRAMs used (Default)
1	1	1M bit DRAMs used

DRAM Configuration Register RB7

Index register port: 22H
Data register port: 23H (R/W)
Index: 6BH

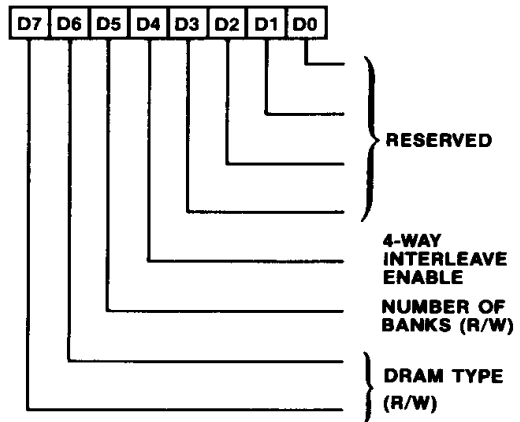


Bits	Function															
1, 0	ROM access wait states control. <table border="1" style="margin-left: 20px;"> <thead> <tr> <th>1</th> <th>0</th> <th>Wait States</th> </tr> </thead> <tbody> <tr> <td>0</td> <td>0</td> <td>0</td> </tr> <tr> <td>0</td> <td>1</td> <td>1</td> </tr> <tr> <td>1</td> <td>0</td> <td>2</td> </tr> <tr> <td>1</td> <td>1</td> <td>3 (Default)</td> </tr> </tbody> </table>	1	0	Wait States	0	0	0	0	1	1	1	0	2	1	1	3 (Default)
1	0	Wait States														
0	0	0														
0	1	1														
1	0	2														
1	1	3 (Default)														
3, 2	EMS memory access wait states. <table border="1" style="margin-left: 20px;"> <thead> <tr> <th>3</th> <th>2</th> <th>Wait States</th> </tr> </thead> <tbody> <tr> <td>0</td> <td>0</td> <td>0</td> </tr> </tbody> </table>	3	2	Wait States	0	0	0									
3	2	Wait States														
0	0	0														
4	EMS enable bit. If set to 0, EMS is disabled (Default). If set to 1, EMS is enabled.															
5	RAM access wait states. If set to 0, accesses have 0 wait state. If set to 1 (Default), accesses will have 1 wait state.															
6	640Kbyte to 1Mbyte RAM relocation bit. A zero does not relocate local RAM. A one (Default) relocates local RAM from 0A0000-0FFFFFF to 100000H-15FFFFH, provided total local RAM is 1 Mbyte only.															

7 Page/Interleaved mode enable. A 0 disables the page/interleaved mode, allowing useage of normal mode for the DRAMs (Default). A 1 enables page/interleaved mode for the DRAMs.

Bank 2/3 Enable Register RB8

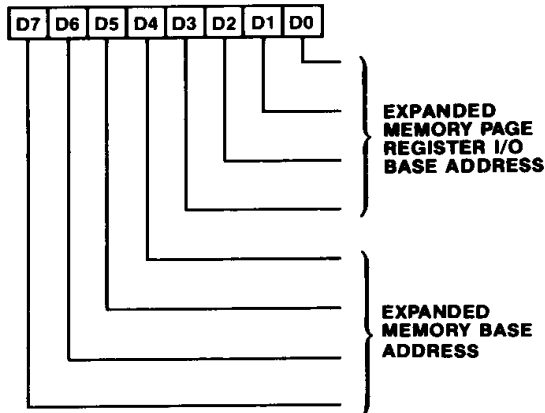
Index register port: 22H
Data register port: 23H
Index: 6CH



Bits	Function															
0-3	Reserved and default to 0*															
4	A zero enable the 2-way page interleaved mode. A one (Default) enables the 4-way page interleaved mode if all 4 banks are the same DRAM devices.															
5	Number of local RAM banks used. 0 = one bank used, non-interleaved mode only (Default). 1 = two banks used.															
7, 6	These bits indicate the local DRAM type as listed: <table border="1" style="margin-left: 20px;"> <thead> <tr> <th>7</th> <th>6</th> <th>DRAM Type</th> </tr> </thead> <tbody> <tr> <td>0</td> <td>0</td> <td>none (Default)</td> </tr> <tr> <td>0</td> <td>1</td> <td>Reserved</td> </tr> <tr> <td>1</td> <td>0</td> <td>256 Kbit</td> </tr> <tr> <td>1</td> <td>1</td> <td>1 Mbit</td> </tr> </tbody> </table>	7	6	DRAM Type	0	0	none (Default)	0	1	Reserved	1	0	256 Kbit	1	1	1 Mbit
7	6	DRAM Type														
0	0	none (Default)														
0	1	Reserved														
1	0	256 Kbit														
1	1	1 Mbit														

EMS Base Address Register RB9

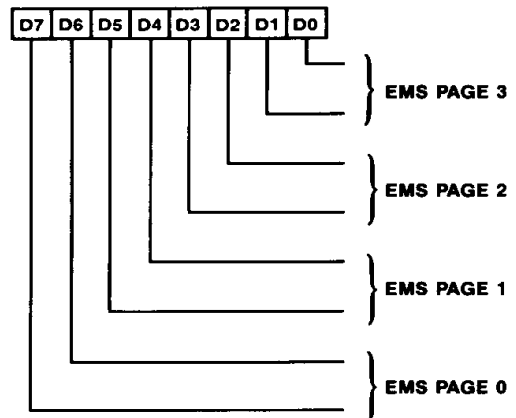
Index register port: 22H
Data register port: 23H (R/W)
Index: 6DH



0	1	0	0	D4000H, D8000H D0000H, D4000H, D8000H, DC000H
0	1	0	1	D4000H, D8000H, DC000H, E0000H
0	1	1	0	D8000H, DC000H, E0000H, E4000H
0	1	1	1	DC000H, E0000H, E4000H, E8000H
1	0	0	0	E0000H, E4000H, E8000H, EC000H

EMS Address Extension Register RB10

Index register port: 22H
Data register port: 23H (R/W)
Index: 6EH



Bits	Function																																								
0-3	These bits are used for the EMS page register I/O base address. The bits are encoded as follows, with unused combinations being reserved: <table border="1" style="margin: 10px auto;"> <thead> <tr> <th>3</th> <th>2</th> <th>1</th> <th>0</th> <th>I/O Base</th> </tr> </thead> <tbody> <tr><td>0</td><td>0</td><td>0</td><td>0</td><td>208H/209H</td></tr> <tr><td>0</td><td>0</td><td>0</td><td>1</td><td>218H/219H</td></tr> <tr><td>0</td><td>1</td><td>0</td><td>1</td><td>258H/259H</td></tr> <tr><td>0</td><td>1</td><td>1</td><td>0</td><td>268H/269H</td></tr> <tr><td>1</td><td>0</td><td>1</td><td>0</td><td>2A8H/2A9H</td></tr> <tr><td>1</td><td>0</td><td>1</td><td>1</td><td>2B8H/2B9H</td></tr> <tr><td>1</td><td>1</td><td>1</td><td>0</td><td>2E8H/2E9H</td></tr> </tbody> </table>	3	2	1	0	I/O Base	0	0	0	0	208H/209H	0	0	0	1	218H/219H	0	1	0	1	258H/259H	0	1	1	0	268H/269H	1	0	1	0	2A8H/2A9H	1	0	1	1	2B8H/2B9H	1	1	1	0	2E8H/2E9H
3	2	1	0	I/O Base																																					
0	0	0	0	208H/209H																																					
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0	1	0	1	258H/259H																																					
0	1	1	0	268H/269H																																					
1	0	1	0	2A8H/2A9H																																					
1	0	1	1	2B8H/2B9H																																					
1	1	1	0	2E8H/2E9H																																					
7-4	These bits are used for selecting the expanded memory base addresses. They are encoded as follows, with all unused combinations being reserved: <table border="1" style="margin: 10px auto;"> <thead> <tr> <th>7</th> <th>6</th> <th>5</th> <th>4</th> <th>EMS Base Addresses</th> </tr> </thead> <tbody> <tr> <td>0</td><td>0</td><td>0</td><td>0</td> <td>C0000H, C4000H, C8000H, CC000H</td> </tr> <tr> <td>0</td><td>0</td><td>0</td><td>1</td> <td>C4000H, C8000H, CC000H, D0000H</td> </tr> <tr> <td>0</td><td>0</td><td>1</td><td>0</td> <td>C8000H, CC000H, D0000H, D4000H</td> </tr> <tr> <td>0</td><td>0</td><td>1</td><td>1</td> <td>CC000H, D0000H,</td> </tr> </tbody> </table>	7	6	5	4	EMS Base Addresses	0	0	0	0	C0000H, C4000H, C8000H, CC000H	0	0	0	1	C4000H, C8000H, CC000H, D0000H	0	0	1	0	C8000H, CC000H, D0000H, D4000H	0	0	1	1	CC000H, D0000H,															
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0	0	0	1	C4000H, C8000H, CC000H, D0000H																																					
0	0	1	0	C8000H, CC000H, D0000H, D4000H																																					
0	0	1	1	CC000H, D0000H,																																					

Bits	Function															
1(A22)	EMS Page 3 address extension bits.															
0(A21)	<table border="1" style="margin: 10px auto;"> <thead> <tr> <th>1</th> <th>0</th> <th>Block of EMS Memory</th> </tr> </thead> <tbody> <tr><td>0</td><td>0</td><td>0 Mbyte to 2 Mbyte</td></tr> <tr><td>0</td><td>1</td><td>2 Mbyte to 4 Mbyte</td></tr> <tr><td>1</td><td>0</td><td>4 Mbyte to 6 Mbyte</td></tr> <tr><td>1</td><td>1</td><td>6 Mbyte to 8 Mbyte</td></tr> </tbody> </table>	1	0	Block of EMS Memory	0	0	0 Mbyte to 2 Mbyte	0	1	2 Mbyte to 4 Mbyte	1	0	4 Mbyte to 6 Mbyte	1	1	6 Mbyte to 8 Mbyte
1	0	Block of EMS Memory														
0	0	0 Mbyte to 2 Mbyte														
0	1	2 Mbyte to 4 Mbyte														
1	0	4 Mbyte to 6 Mbyte														
1	1	6 Mbyte to 8 Mbyte														
3(A22)	EMS Page 2 address extension bits.															
2(A21)	<table border="1" style="margin: 10px auto;"> <thead> <tr> <th>3</th> <th>2</th> <th>Block of EMS Memory</th> </tr> </thead> <tbody> <tr><td>0</td><td>0</td><td>0 Mbyte to 2 Mbyte</td></tr> <tr><td>0</td><td>1</td><td>2 Mbyte to 4 Mbyte</td></tr> <tr><td>1</td><td>0</td><td>4 Mbyte to 6 Mbyte</td></tr> <tr><td>1</td><td>1</td><td>6 Mbyte to 8 Mbyte</td></tr> </tbody> </table>	3	2	Block of EMS Memory	0	0	0 Mbyte to 2 Mbyte	0	1	2 Mbyte to 4 Mbyte	1	0	4 Mbyte to 6 Mbyte	1	1	6 Mbyte to 8 Mbyte
3	2	Block of EMS Memory														
0	0	0 Mbyte to 2 Mbyte														
0	1	2 Mbyte to 4 Mbyte														
1	0	4 Mbyte to 6 Mbyte														
1	1	6 Mbyte to 8 Mbyte														

5(A22)	EMS Page 1 address extension bits.	
4(A21)	5	4 Block of EMS Memory
	0	0 0 Mbyte to 2 Mbyte
	0	1 2 Mbyte to 4 Mbyte
	1	0 4 Mbyte to 6 Mbyte
	1	1 6 Mbyte to 8 Mbyte
7(A22)	EMS Page 0 address extension bits.	
6(A21)	7	6 Block of EMS Memory
	0	0 0 Mbyte to 2 Mbyte
	0	1 2 Mbyte to 4 Mbyte
	1	0 4 Mbyte to 6 Mbyte
	1	1 6 Mbyte to 8 Mbyte

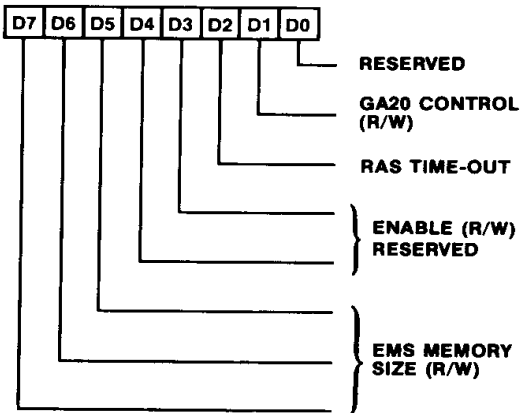
Address lines A22 and A21 are used in EMS Address translation logic.

Miscellaneous Register RB12

Index register port: 22H

Data register port: 23H

Index: 6FH



Bits	Function
0	Reserved and default to 0.*
1	This bit is used for Address line A20 control and provides OS/2 optimization while switching between real and protected modes: If the bit is set to 0 it enables CPUA20 onto A20. The bit default to 1 and sets A20 = 0.

2	This bit is used to enable the RAS time-out counter for page mode operation. The counter is disabled if set to 0 (Default) and is enabled if set to 1.																																				
3, 4	Reserved and default to 1 (bit 4), 0 (bit 3).																																				
7-5	These bits are used to set the EMS memory space according to the following coding:																																				
	<table border="1"> <thead> <tr> <th>7</th> <th>6</th> <th>5</th> <th>EMS Memory Size</th> </tr> </thead> <tbody> <tr> <td>0</td> <td>0</td> <td>0</td> <td>less than 1 Mbyte</td> </tr> <tr> <td>0</td> <td>0</td> <td>1</td> <td>1 Mbyte</td> </tr> <tr> <td>0</td> <td>1</td> <td>0</td> <td>2 Mbytes</td> </tr> <tr> <td>0</td> <td>1</td> <td>1</td> <td>3 Mbytes</td> </tr> <tr> <td>1</td> <td>0</td> <td>0</td> <td>4 Mbytes</td> </tr> <tr> <td>1</td> <td>0</td> <td>1</td> <td>5 Mbytes</td> </tr> <tr> <td>1</td> <td>1</td> <td>0</td> <td>6 Mbytes</td> </tr> <tr> <td>1</td> <td>1</td> <td>1</td> <td>7 Mbytes</td> </tr> </tbody> </table>	7	6	5	EMS Memory Size	0	0	0	less than 1 Mbyte	0	0	1	1 Mbyte	0	1	0	2 Mbytes	0	1	1	3 Mbytes	1	0	0	4 Mbytes	1	0	1	5 Mbytes	1	1	0	6 Mbytes	1	1	1	7 Mbytes
7	6	5	EMS Memory Size																																		
0	0	0	less than 1 Mbyte																																		
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1	0	0	4 Mbytes																																		
1	0	1	5 Mbytes																																		
1	1	0	6 Mbytes																																		
1	1	1	7 Mbytes																																		

EMS Page Registers

Page 0	2X8/2X9H
Page 1	42X8/42X9H
Page 2	82X8/82X9H
Page 3	C2X8/C2X9H

Bits	Function
0-6	0 - A14 1 - A15 2 - A16 3 - A17 4 - A18 5 - A19 6 - A20
7	0 - page disable 1 - page enable

X can be 0, 1, 5, 6, A, B, E

*The reserved bits are recommended to be initialized to 1.

2.6 Absolute Maximum Ratings

Parameter	Symbol	Min.	Max.	Units
Supply Voltage	V_{CC}	—	7.0	V
Input Voltage	V_I	-0.5	5.5	V
Output Voltage	V_O	-0.5	5.5	V
Operating Temperature	T_{OP}	-25°	85°	C
Storage Temperature	T_{STG}	-40°	125°	C

NOTE: Permanent device damage may occur if Absolute Maximum Ratings are exceeded. Functional operation should be restricted to the conditions described under Operating Conditions.

2.7 82C212 Operating Conditions

Parameter	Symbol	Min.	Max.	Units
Supply Voltage	V_{CC}	4.75	5.25	V
Ambient Temperature	T_A	0°	70°	C

2.8 82C212 DC Characteristics

Parameter	Symbol	Min.	Max.	Units
Input Low Voltage	V_{IL}	—	0.8	V
Input High Voltage	V_{IH}	2.0	—	V
Output Low Voltage $I_{OL} = 4\text{mA}$	V_{OL}	—	0.45	V
Output High Voltage $I_{OH} = -4\text{mA}$	V_{OH}	2.4	—	V
Input Low Current $0 < V_{IN} < V_{CC}$	I_{IL}	—	+10	μA
Power Supply Current @ 16MHz	I_{CC}	—	75	mA
Output High-Z Leakage Current $0.45 < V_{OUT} < V_{CC}$	I_{OZ1}	—	+10	μA
Standby Power Supply Current	I_{CCSB}	—	1.0	mA

2.9 82C212-12, 82C212-16 AC Characteristics

($T_A = 0^\circ\text{C}$ to 70°C , $V_{CC} = 5\text{V} \pm 5\%$)

Sym	Description	Min.	Typ.	Max.	Units
t1	$\overline{\text{RAS}}_i$ active delay from CLK2^\dagger	11		16	ns
t2	$\overline{\text{RAS}}_i$ inactive delay from CLK2^\dagger	15		25	ns
t3	DLYOUT active delay from $\overline{\text{RAS}}_i^\dagger$	0		4	ns
t4	DLYOUT inactive delay from $\overline{\text{RAS}}_i^\dagger$	0		6	ns
t5	Column address stable from DLYO †	8		18	ns
t6	Column address hold from DLYO †	6			ns
t7	$\overline{\text{CAS}}_i$ active delay from DLY1 †	7		14	ns
t8	$\overline{\text{CAS}}_i$ inactive delay from DLY1 †	11		18	ns
t9	$\overline{\text{AF16}}$ active delay from CLK2^\dagger	7		16(19)	ns
t10	$\overline{\text{AF16}}$ inactive delay from CLK2^\dagger	8		18(21)	ns
t11	$\overline{\text{READY}}$ active delay from CLK2^\dagger	15		25	ns
t12	$\overline{\text{READY}}$ inactive delay from CLK2^\dagger	11		20	ns
t13	$\overline{\text{DRD}}$ active delay from CLK2^\dagger	10		19	ns
t14	$\overline{\text{DRD}}$ hold from DLE †	13			ns
t15	DLE active delay from $\overline{\text{DLY1}}^\dagger$	6		16	ns
t16	DLE inactive delay from CLK2^\dagger	9		18	ns
t17	$\overline{\text{LMEGCS}}$ active from CLK2^\dagger	12		21	ns
t18	$\overline{\text{LMEGCS}}$ inactive from CLK2^\dagger	11		20	ns
t19	$\overline{\text{GA20}}$ valid delay from CPU $\langle\text{A20}\rangle$ valid	7		16 (20)	ns
t20	$\overline{\text{GA20}}$ invalid delay from CPU $\langle\text{A20}\rangle$ invalid	4		12 (16)	ns
t22	$\overline{\text{MWE}}$ active delay from CLK2^\dagger	11		20	ns
t23	$\overline{\text{MWE}}$ inactive delay from CLK2^\dagger	4		12	ns
t26	$\overline{\text{CAS}}_i$ active delay from CLK2^\dagger	10		19 (25)	ns
t27	$\overline{\text{CAS}}_i$ inactive delay from CLK2^\dagger	11		21(26)	ns
t28	$\overline{\text{DRD}}$ inactive delay from CLK2^\dagger	12		23	ns
t29	$\overline{\text{CAS}}_i$ inactive delay from DLE inactive	2			ns
t30	$\overline{\text{RAS}}_i$ active delay from CLK2^\dagger	10.5		16	ns
t31	Row address set up time to $\overline{\text{RAS}}_i^\dagger$	8			ns
t32	Row address hold time from CLK2^\dagger	6		22	ns
t33	$\overline{\text{RAS}}_i$ inactive delay from CLK2^\dagger	15		25	ns

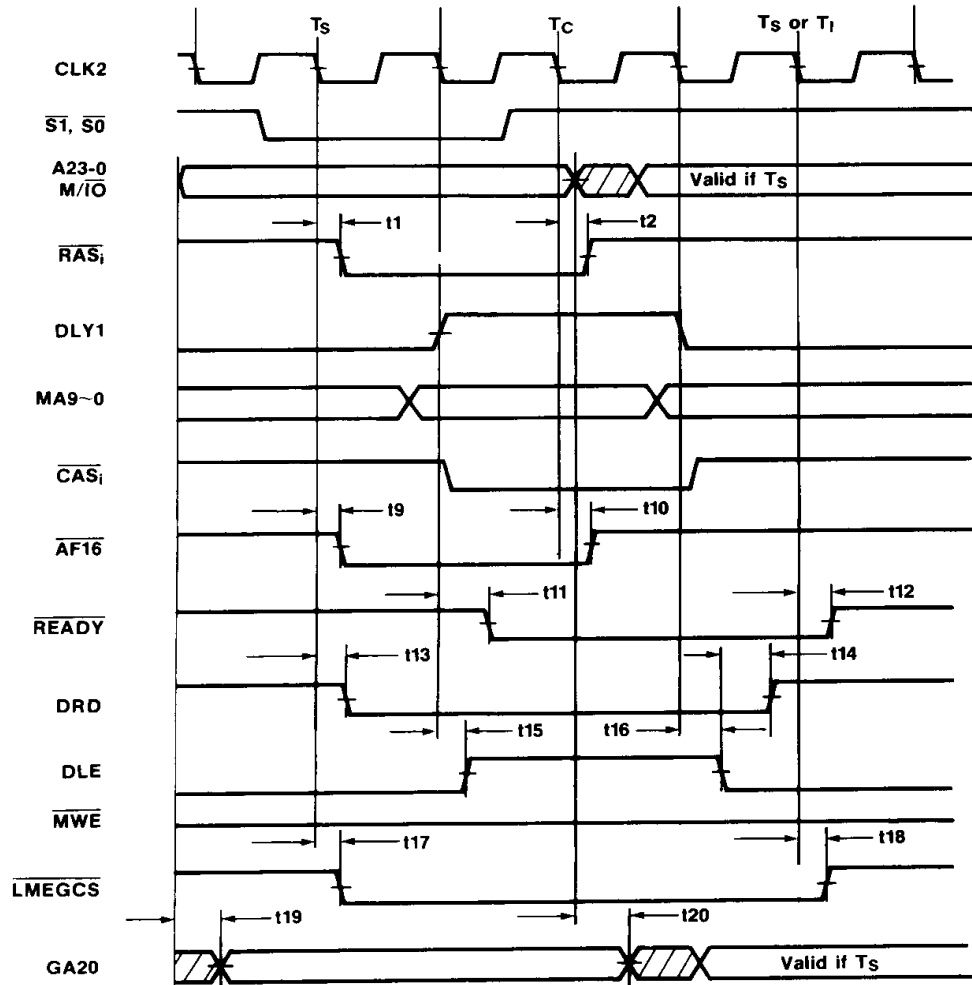
2.9 82C212-12, 82C212-16 AC Characteristics (Continued)

($T_A = 0^\circ\text{C}$ to 70°C , $V_{CC} = 5V \pm 5\%$)

Sym	Description	Min.	Typ.	Max.	Units
t34	$\overline{\text{RAS}}_i$ precharge time (Interleaved Mode)			$4 \times \text{CLK2}$	
t35	$\overline{\text{ROMCS}}$ active from $\text{CLK2}\dagger$	11		20	ns
t36	$\overline{\text{ROMCS}}$ inactive from $\text{CLK2}\dagger$	10		20	ns
t37	DLE hold time from $\overline{\text{DRD}}$	0		7	ns
t38	$\overline{\text{RAS}}_{0-3}$ inactive from $\overline{\text{REF}}\dagger$	13		24	ns
t39	$\overline{\text{RAS}}_{0,3}$ active from $\overline{\text{XMEMR}}\dagger$	9		17	ns
t40	$\overline{\text{RAS}}_{0,3}$ inactive from $\overline{\text{XMEMR}}\dagger$	10		19	ns
t41	$\overline{\text{RAS}}_{1,2}$ active from $\overline{\text{RAS}}_{0,3}\dagger$	7		15	ns
t42	$\overline{\text{RAS}}_{1,2}$ inactive from $\overline{\text{RAS}}_{0,3}\dagger$	11		20	ns
t43	Address setup time from $\overline{\text{XMEMR}}\dagger$	10			ns
t44	Address hold time from $\overline{\text{REF}}\dagger$	4			ns
t45	Refresh address delay	0			ns
t47	$\overline{\text{LMEGCS}}$ delay from $\overline{\text{REF}}\dagger$	8		16	ns
t48	$\overline{\text{LMEGCS}}$ delay from $\overline{\text{REF}}\dagger$	10		19	ns
t49	$\overline{\text{RAS}}_{0-3}$ inactive from $\text{HLDA}1\dagger$	11		20	ns
t50	$\overline{\text{RAS}}_i$ active from command active	10		18	ns
t51	$\overline{\text{RAS}}_i$ inactive from command inactive	12		21	ns
t54	Column address stable from $\text{DLY}0\dagger$	9		18	ns
t55	$\overline{\text{CAS}}_i$ active delay from $\text{DLY}1\dagger$ (while XMEMW active)	6		14	ns
t56	$\overline{\text{CAS}}_i$ inactive delay from command inactive	9		18	ns
t57	$\overline{\text{AF16}}$ active from command active	9		17	ns
t58	$\overline{\text{AF16}}$ inactive from command inactive	6		14	ns

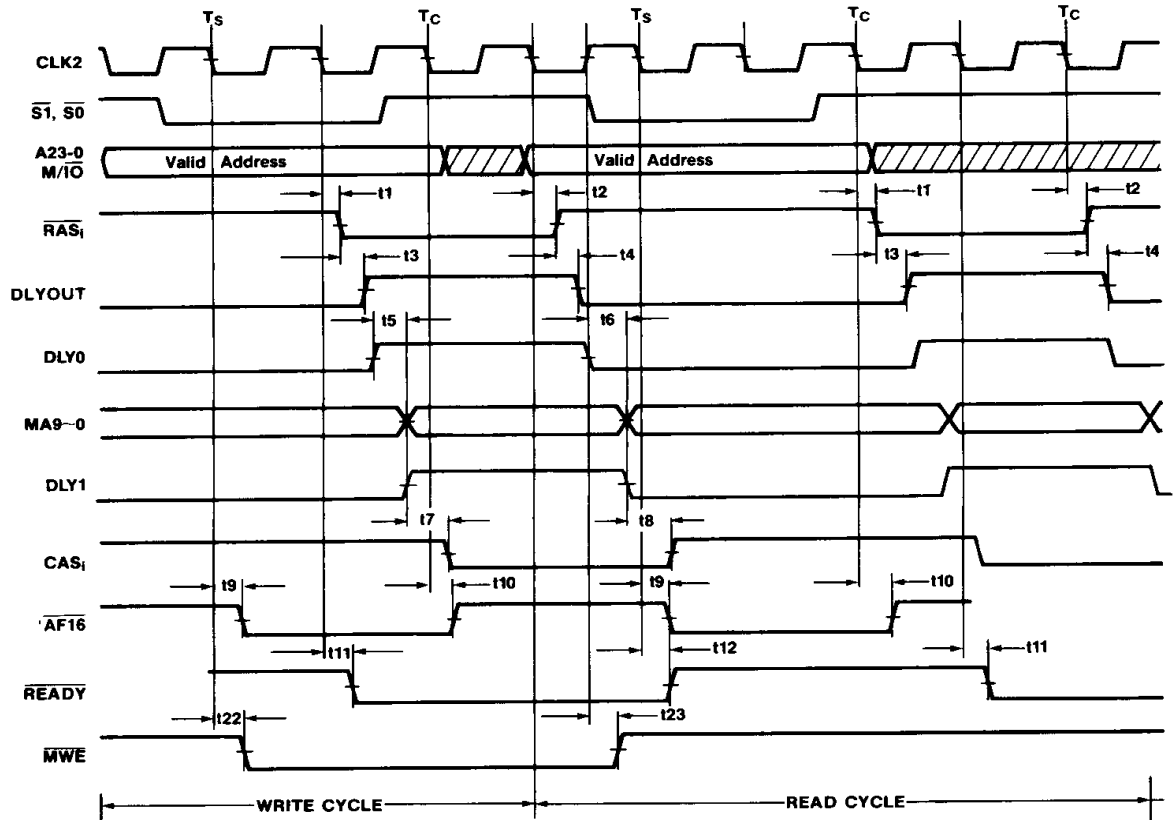
Note: Value inside () are 12 MHz timing.

2.10 82C212 Timing Diagrams



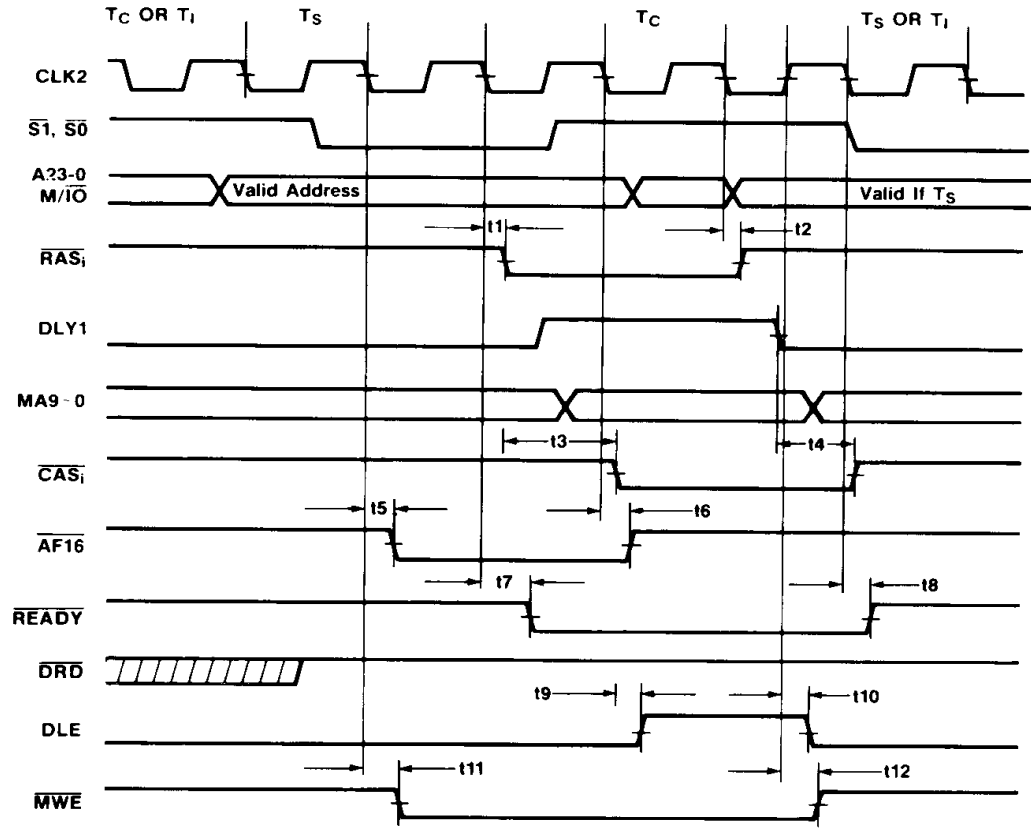
Non-Interleave Mode—Read, 0WS

2.10 82C212 Timing Diagrams (Continued)



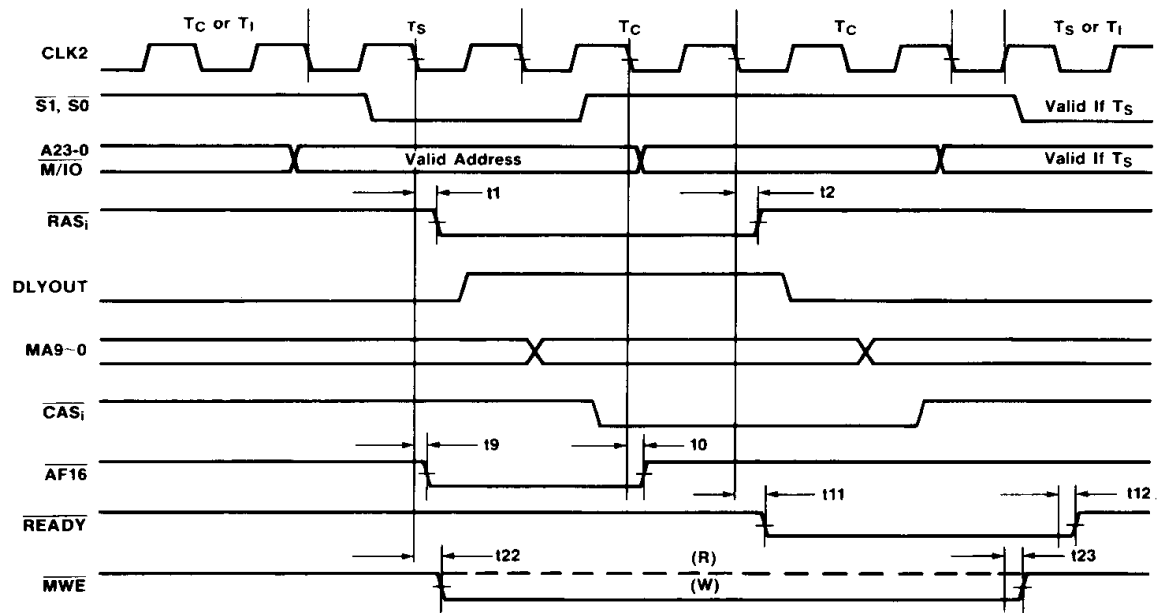
Non-Interleave Mode—Write Followed by Read, OWS

2.10 82C212 Timing Diagrams (Continued)



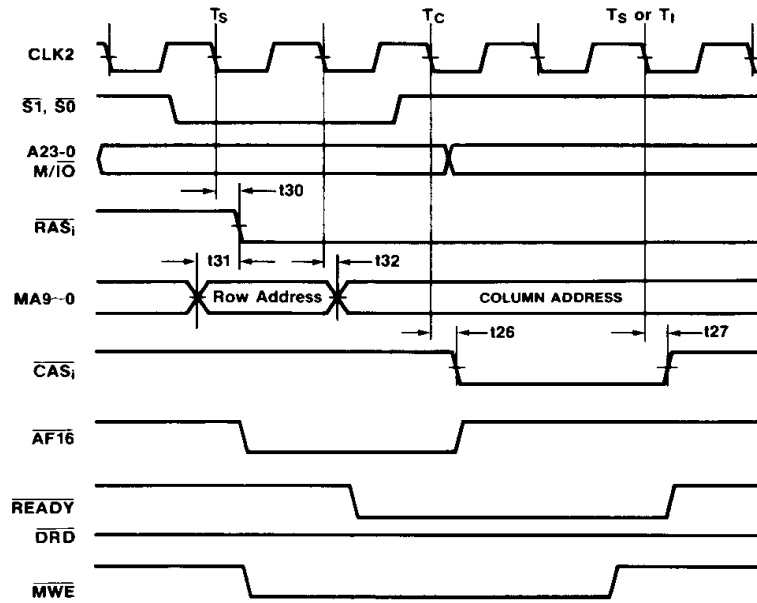
Non-Interleave Mode—0WS, Write

2.10 82C212 Timing Diagrams (Continued)



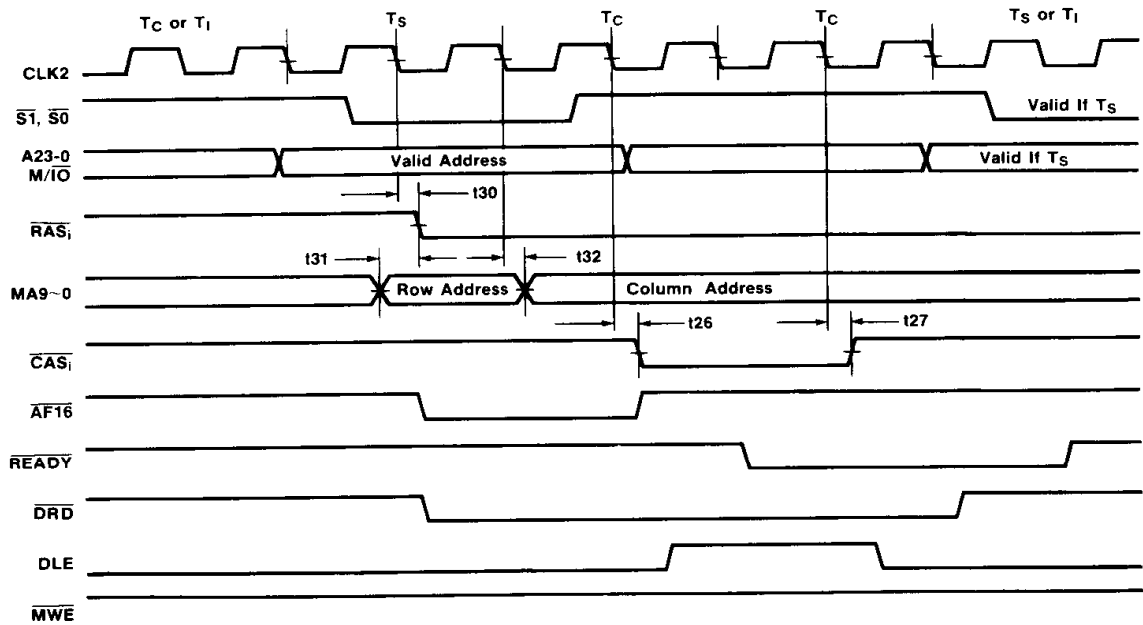
Non-Interleave Mode—1WS, Read, Write

2.10 82C212 Timing Diagrams (Continued)



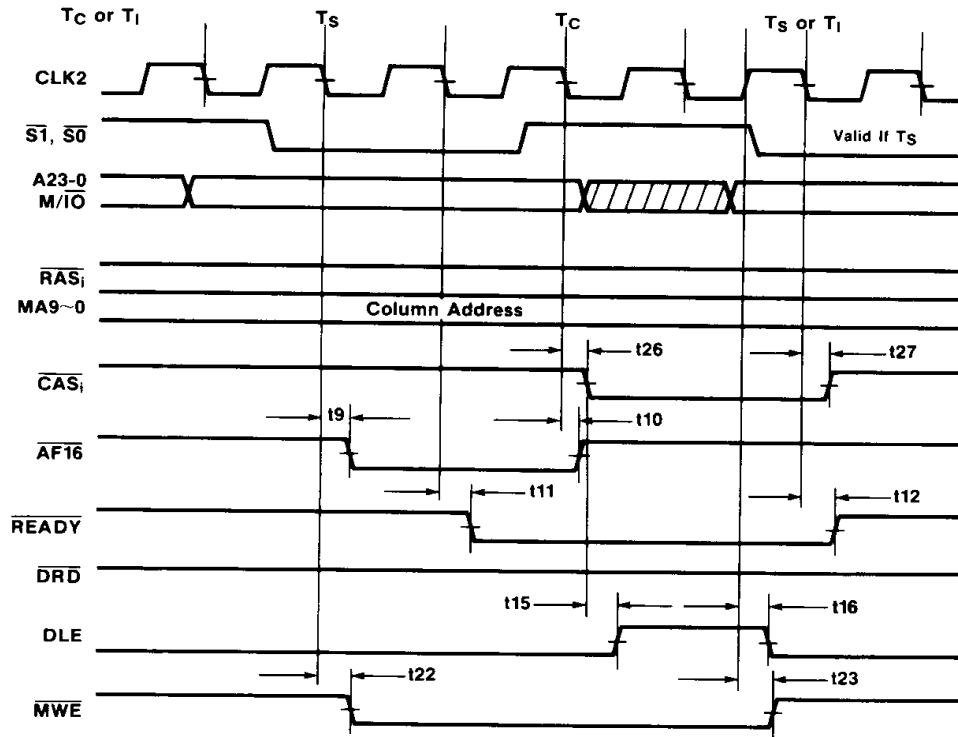
Interleave Mode—Write Cycle with RAS Being Inactive, 0WS

2.10 82C212 Timing Diagrams (Continued)



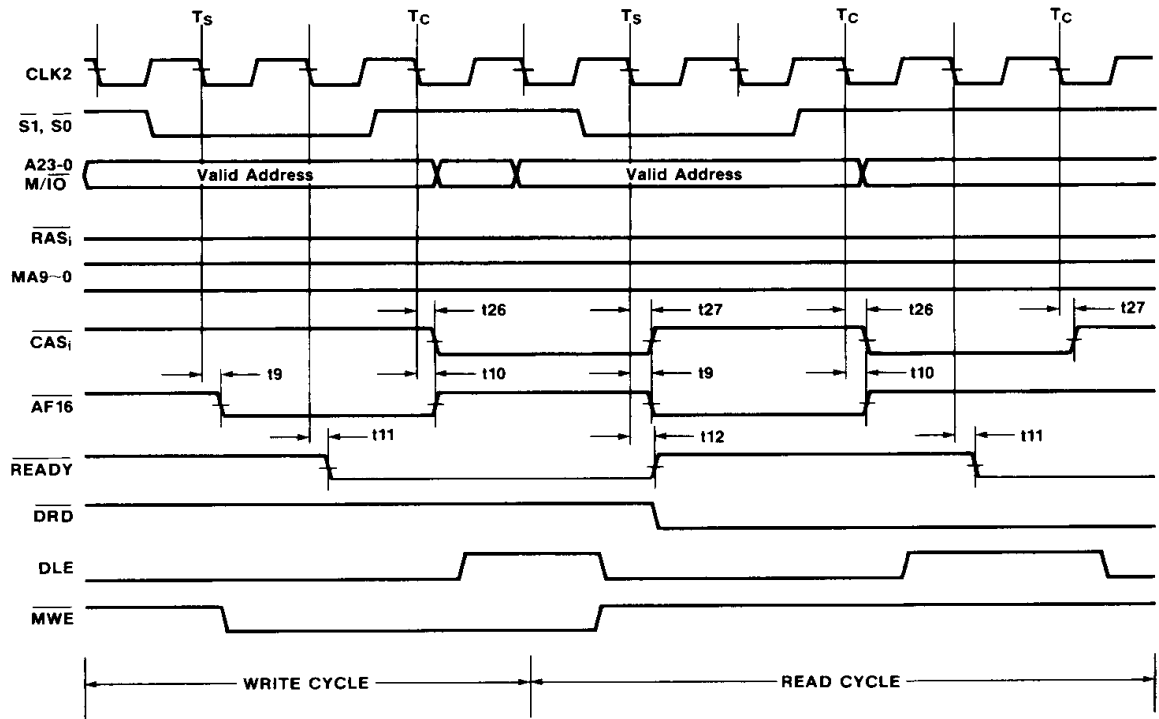
Interleave Mode—Read Cycle with RAS Being Inactive, 0WS

2.10 82C212 Timing Diagrams (Continued)



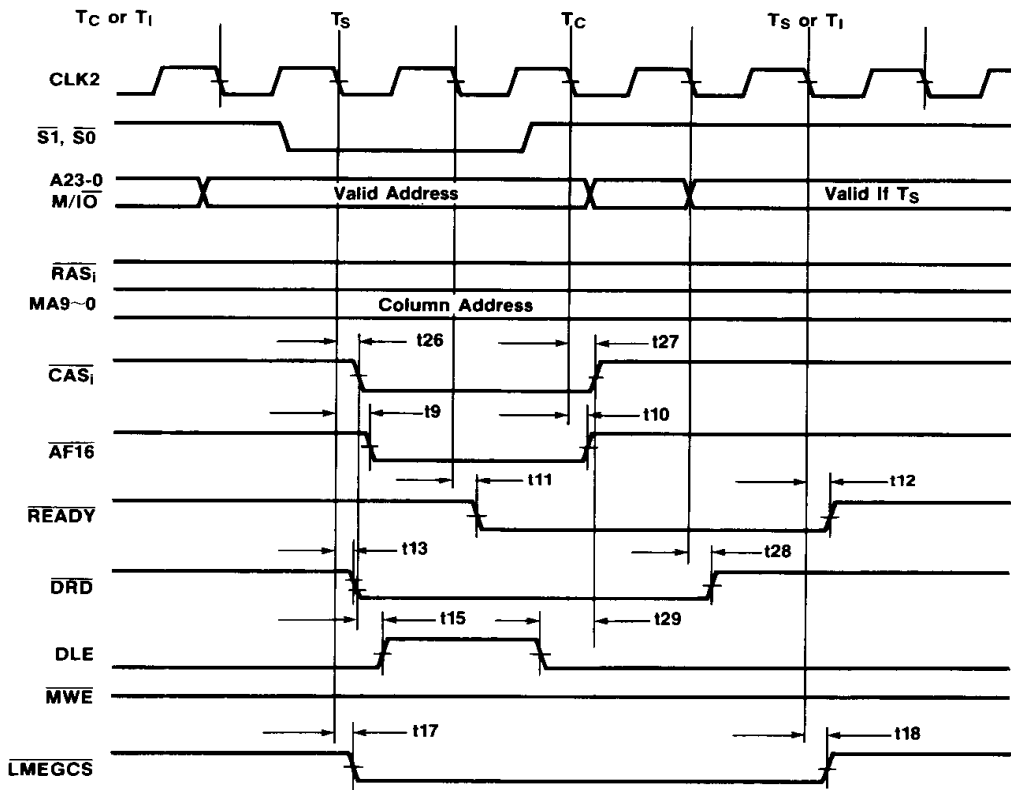
Interleave Mode—Write, 0WS (RAS active)

2.10 82C212 Timing Diagrams (Continued)



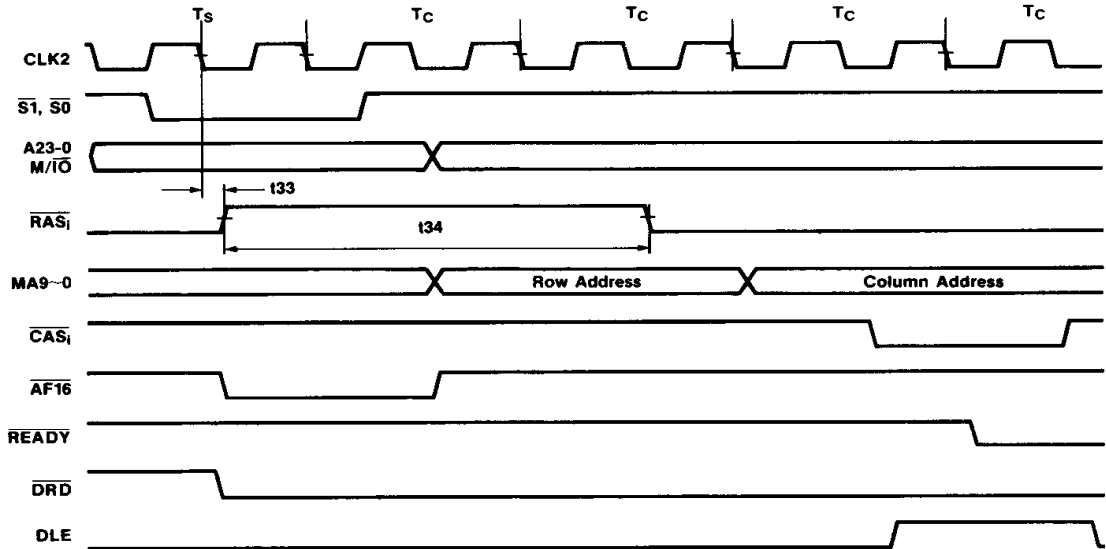
Interleave Mode—Read After Write, 0WS (RAS active)

2.10 82C212 Timing Diagrams (Continued)



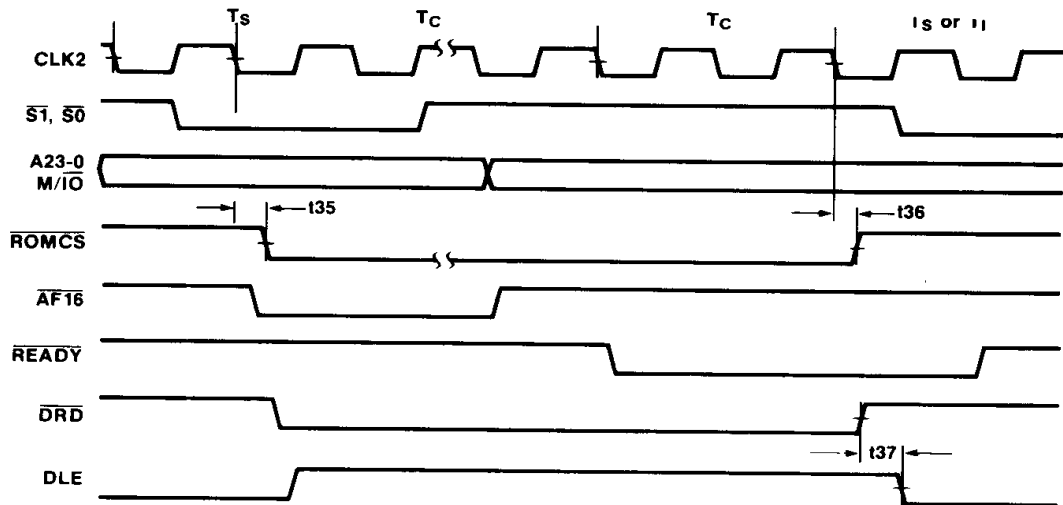
Interleave Mode—Read, 0WS (RAS active)

2.10 82C212 Timing Diagrams (Continued)



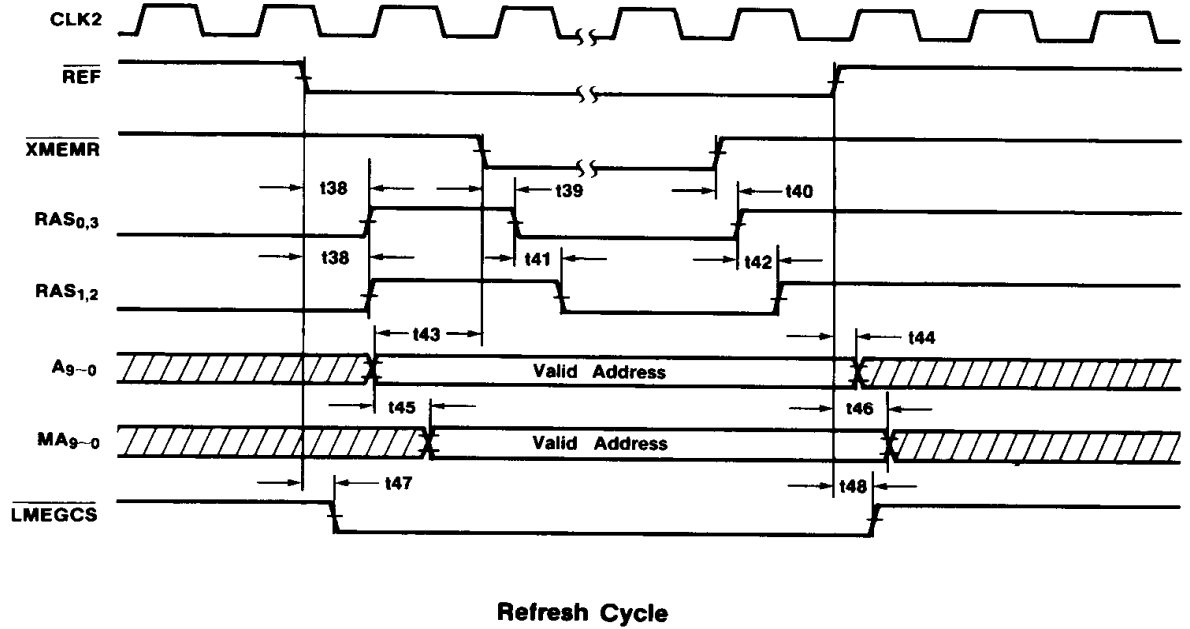
Interleave Mode—Read Miss Cycle

2.10 82C212 Timing Diagrams (Continued)

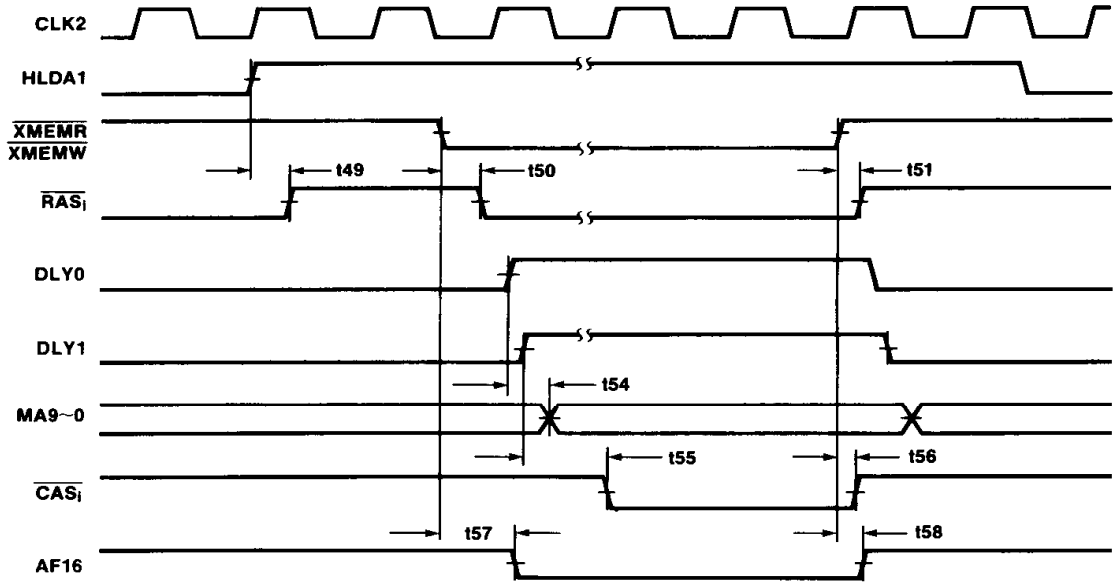


ROM Read Cycle

2.10 82C212 Timing Diagrams (Continued)



2.10 82C212 Timing Diagrams (Continued)



DMA Cycle

3 82C215 DATA/ADDRESS BUFFER

3.1 Features

- Bus Conversion logic for 16 bit to 8 bit transfers
- Parity generation/detection logic

3.2 Functional Description

Figure 3.1 is a block diagram of the 82C215 Data/Address buffer. It consists of four modules:

- Address buffers and latches
- Data buffers and latches
- Bus conversion logic
- Parity generation/detection logic

3.2.1 Address Buffers and Latches

The 82C215 provides the address buffering between the CPU address lines A1-A16 and the XA1-XA16 lines. These buffers drive 4 mA output low currents (I_{OL}). The CPU address lines are latched by IALE to generate the X-Address lines when HLDA is inactive.

3.2.2 Data Buffers and Latches

The 82C215 provides the buffering between the CPU data bus (D0-D15) and the memory data bus (MD0-MD15). The D0-D15 lines drive 4 mA output low currents (I_{OL}). The MD0-MD15 lines drive 8 mA I_{OL} . The enable signal for the latch between the Memory Data bus and the CPU Data bus is controlled by \overline{DRD} , HLDA and the action codes. This allows 16 bit reads from 8 bit peripherals controlled by the 82C211.

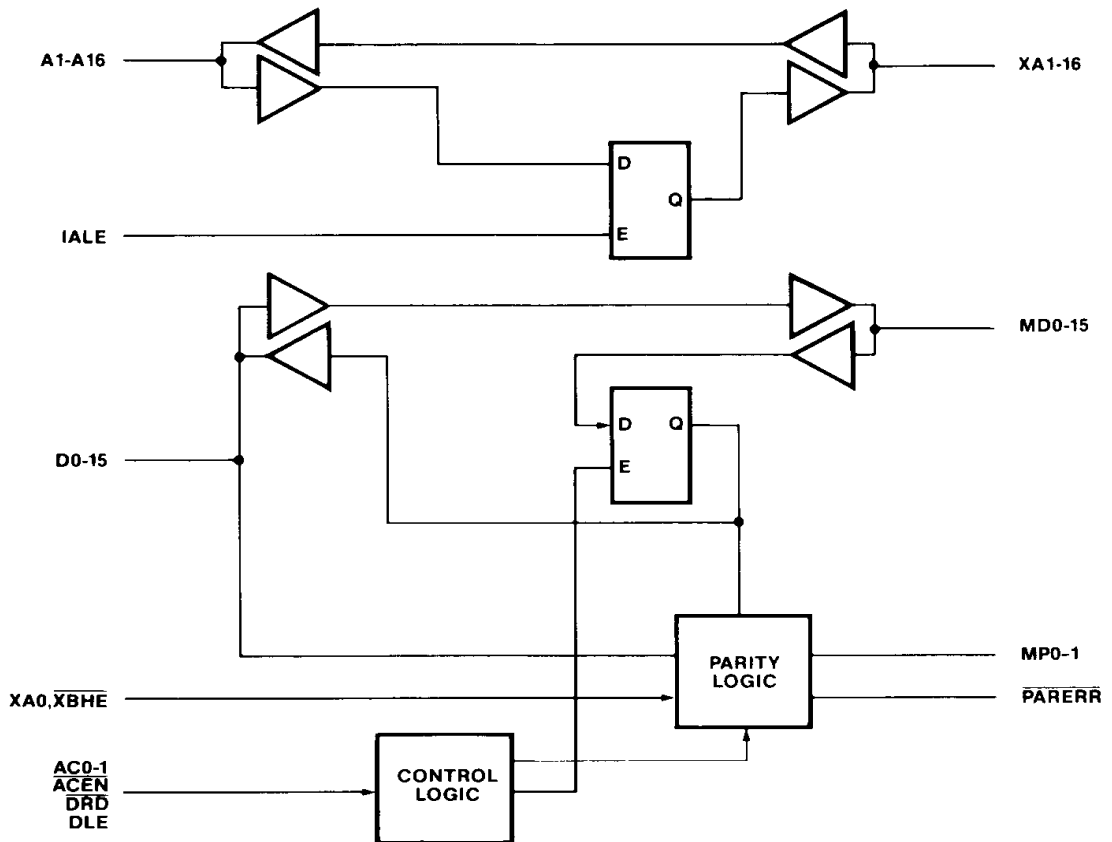


Figure 3.1 82C215 Block Diagram

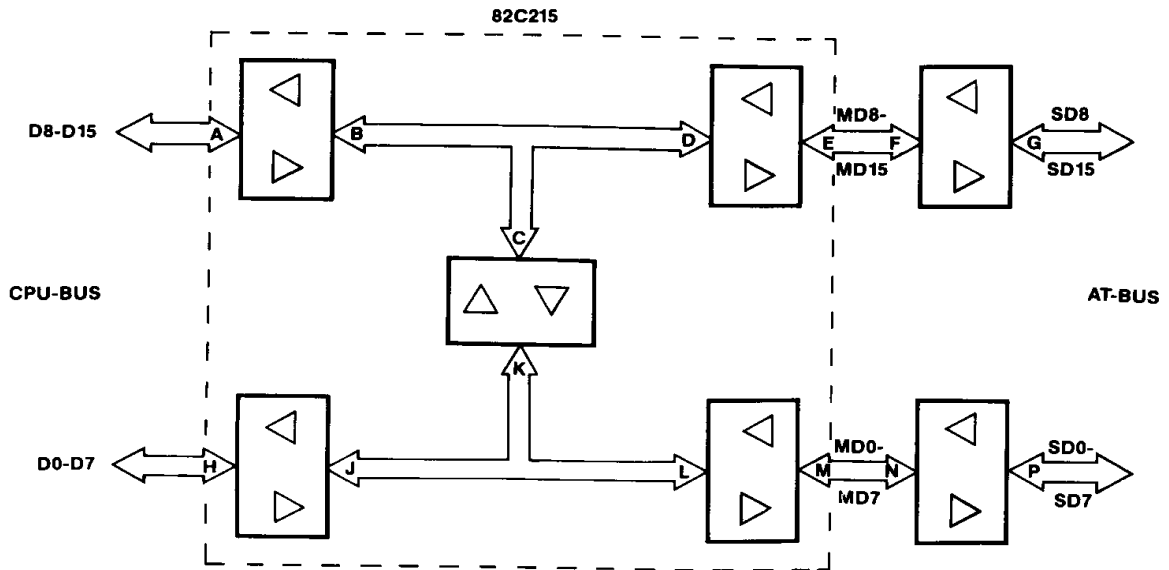


Figure 3.2 Bus Conversion Data Paths

3.3.3 Bus Conversion Logic

The 82C215 provides data bus conversion when the 16 bit CPU reads from or writes to 8 bit devices. It also provides bus conversion for Master/DMA cycles. There are six possible cases, as seen in Table 3.1 in conjunction with Figure 3.2. These conversions are controlled by the action codes which are qualified by ACEN from the 82C211.

3.3.4 Parity Generation/Detection Logic

For local RAM write cycles, the 82C215 generates even parity for each of the two bytes of the data word. These valid even parity bits are written to the parity bits MP0, MP1 in the local DRAMs. During a local memory read cycle, the 82C215 checks for even parity for each MD byte read. If the parity is detected as being odd, the 82C215 flags a parity error on the PARERR output line to the 82C211. The 82C211 distinguishes between local ROM and RAM cycles before sampling PARERR.

Table 3.1

AC1	AC0	Cycle	Operation	Data Path
0	0	CPU	16 bit write	A-B-D-E-F-G and H-J-L-M-N-P
0	0	CPU	8 bit LO write	H-J-L-M-N-P
0	1	CPU	16 bit read	G-F-E-D-B-A and P-N-M-L-J-H
0	1	CPU	8 bit LO read	P-N-M-L-J-H
1	0	CPU	8 bit HI write	A-B-C-K-L-M-N-P
1	1	CPU	8 bit HI read	P-N-M-L-K-C-B-A
1	0	DMA/MASTER	8 bit HI write	P-N-M-L-K-C-D-E-F-G
1	1	DMA/MASTER	8 bit HI read	G-F-E-D-C-K-L-M-N-P

3.4 Absolute Maximum Ratings

Parameter	Symbol	Min.	Max.	Units
Supply Voltage	V_{CC}	—	7.0	V
Input Voltage	V_I	-0.5	5.5	V
Output Voltage	V_O	-0.5	5.5	V
Operating Temperature	T_{OP}	-25°	85°	C
Storage Temperature	T_{STG}	-40°	125°	C

NOTE: Permanent device damage may occur if Absolute Maximum Ratings are exceeded. Functional operation should be restricted to the conditions described under Operating Conditions.

3.5 82C215 Operating Conditions

Parameter	Symbol	Min.	Max.	Units
Supply Voltage	V_{CC}	4.75	5.25	V
Ambient Temperature	T_A	0°	70°	C

3.6 82C215 DC Characteristics

Parameter	Symbol	Min.	Max.	Units
Input Low Voltage	V_{IL}	—	0.8	V
Input High Voltage	V_{IH}	2.0	—	V
Output Low Voltage $I_{OL} = 4\text{mA}$	V_{OL}	—	0.45	V
Output High Voltage $I_{OH} = -4\text{mA}$	V_{OH}	2.4	—	V
Input Current $0 < V_{IN} < V_{CC}$	I_{IL}	—	± 10	μA
Power Supply Current @ 16MHz	I_{CC}	—	80	mA
Output High-Z Leakage Current $0.45 < V_{OUT} < V_{CC}$	I_{OZ1}		± 10	μA
Standby Power Supply Current	I_{CCSB}	—	1.0	mA

3.7 82C215-12, 82C215-16 AC Characteristics

($T_A = 0^\circ\text{C}$ to 70°C , $V_{CC} = 5\text{V} \pm 5\%$)

Sym	Description	Min.	Typ.	Max.	Units
t1	MD bus 3-stated after $\overline{\text{DRD}}$ active	7.5		24	ns
t2	MD bus valid to D bus valid	8		18.5	ns
t3a	MD bus being driven after $\overline{\text{DRD}}$ inactive	7.5		28	ns
t3b	MP0, MP1 being driven after $\overline{\text{DRD}}$ inactive	6		23	ns
t4	D bus invalid after $\overline{\text{DRD}}$ inactive	4		13	ns
t5	D bus 3-stated after $\overline{\text{DRD}}$ inactive	6		15	ns
t6	D bus valid to MD bus valid	11		19	ns
t7	D bus valid to MP1, MP0 valid	11		20	ns
t8	$\overline{\text{ACEN}}$ active to D bus valid	16		27	ns
t9	AC code valid to MD bus valid	10		19	ns
t10	AC code invalid to MD bus invalid	11		20	ns
t11	DLE inactive to $\overline{\text{PARERR}}$ enabled	17		30	ns
t12	$\overline{\text{DRD}}$ inactive to $\overline{\text{PARERR}}$ disabled	17		28	ns
t13	IALE active to XA bus valid	11		19	ns

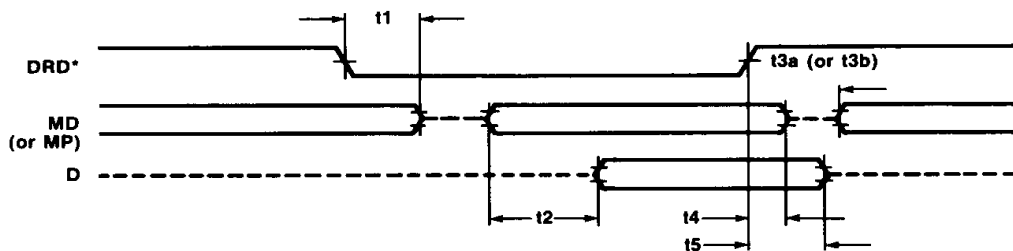
3.7 82C215-12, 82C215-16 AC Characteristics (Continued)

($T_A = 0^\circ\text{C}$ to 70°C , $V_{CC} = 5\text{V} \pm 5\%$)

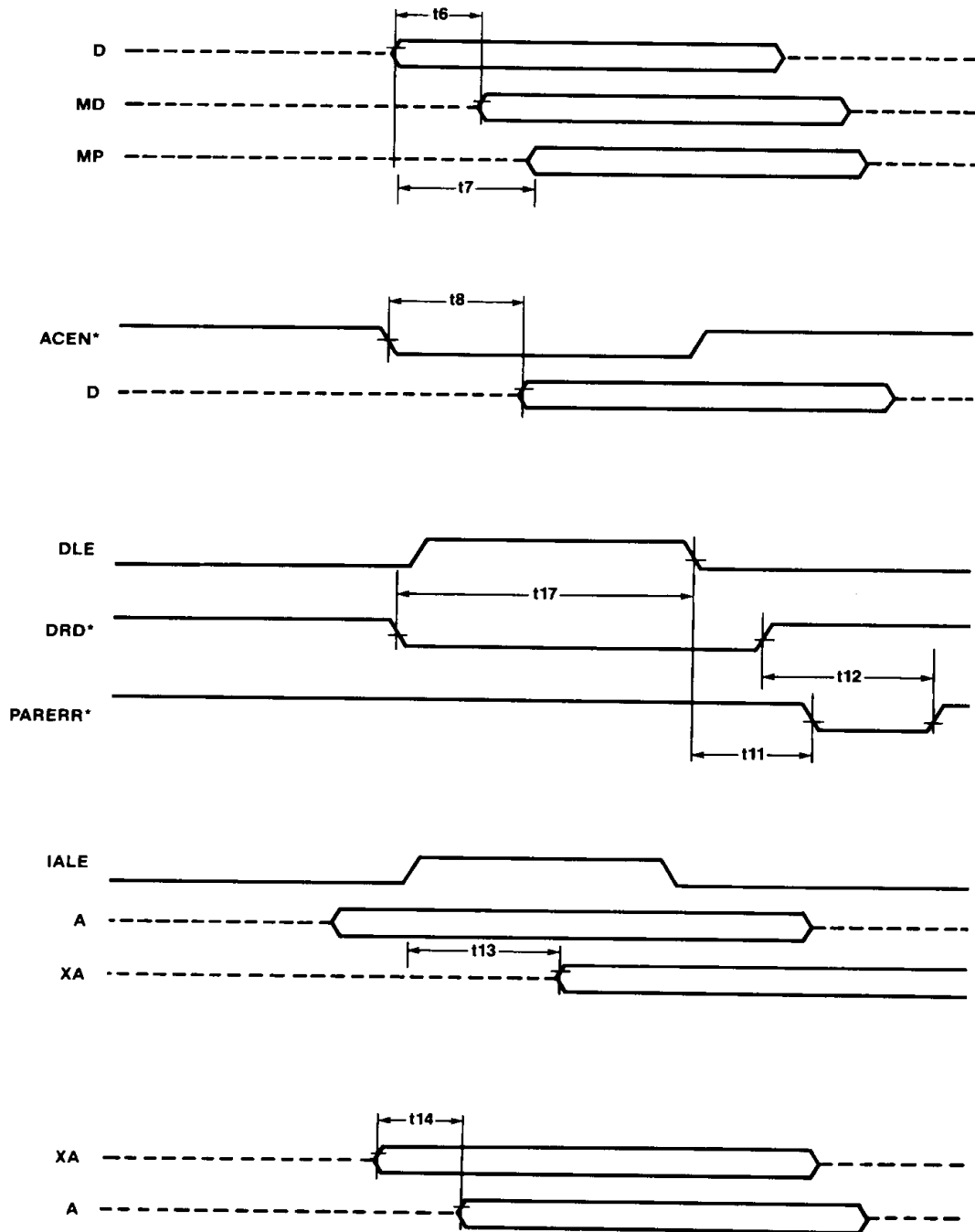
Sym	Description	Min.	Typ.	Max.	Units
t14	XA bus valid to A bus valid	7		16 (19)	ns
t15	MD, MP setup time to DLE trailing edge	0.0			ns
t16	MD, MP hold time from DLE trailing edge	6.0			ns
t17	$\overline{\text{DRD}}$ setup time to DLE trailing edge	12			ns
t19	MD bus hold time from $\overline{\text{ACEN}}$ trailing edge	7.5			ns
t20	MD bus valid to MP valid during DMA memory write cycle	14		24	ns
t21	MD high byte valid to MD low byte valid during DMA high memory read cycle	10		19	ns
t22	AC code valid to MD high byte valid during DMA high memory write cycle	9		18	ns
t23	AC code valid to MP valid during DMA high memory write cycle	17		28	ns

Note: Values inside () are 12 MHz timing.

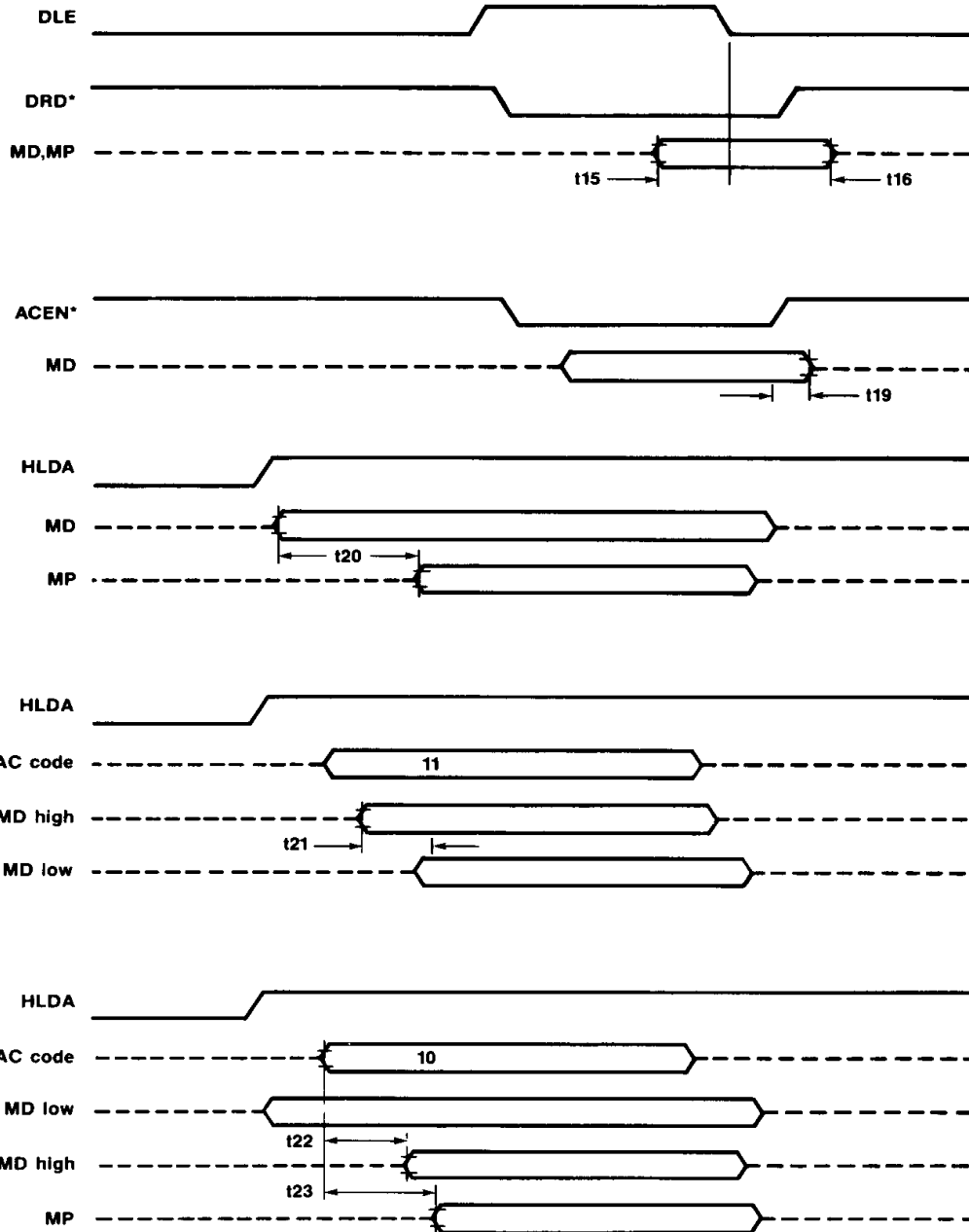
3.8 82C215 Timing Diagrams



3.8 82C215 Timing Diagrams (Continued)



3.8 82C215 Timing Diagrams (Continued)



Load Circuit Measurement Conditions

Parameter	Output Type	Symbol	C_L (pF)	R_1 (Ω)	R_L (Ω)	SW_1	SW_2
Propagation Delay Time	Totem pole	t_{PLH}	50	—	1.0K	OFF	ON
	3-state	t_{PHL}					
Propagation Delay Time	Bidirectional						
	Open drain or Open Collector	t_{PLH} t_{PHL}	50	0.5K	—	ON	OFF
Disable Time	3-state	t_{PLZ}	5	0.5K	1.0K	ON	OFF
	Bidirectional	t_{PHZ}					
Enable Time	3-state	t_{PZL}	50	0.5K	1.0K	ON	ON
	Bidirectional	t_{PZH}					

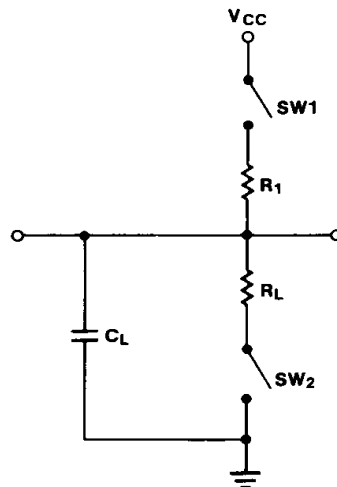
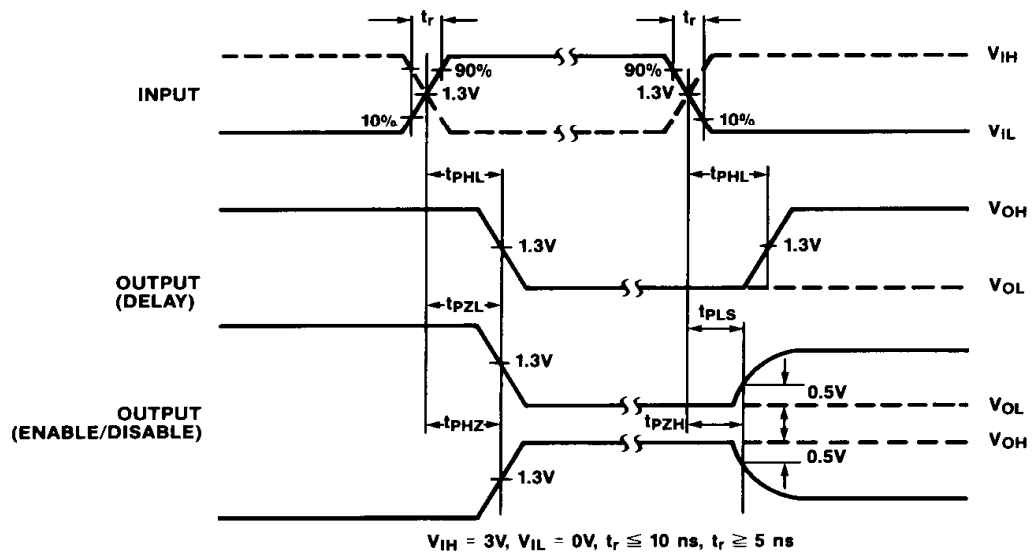
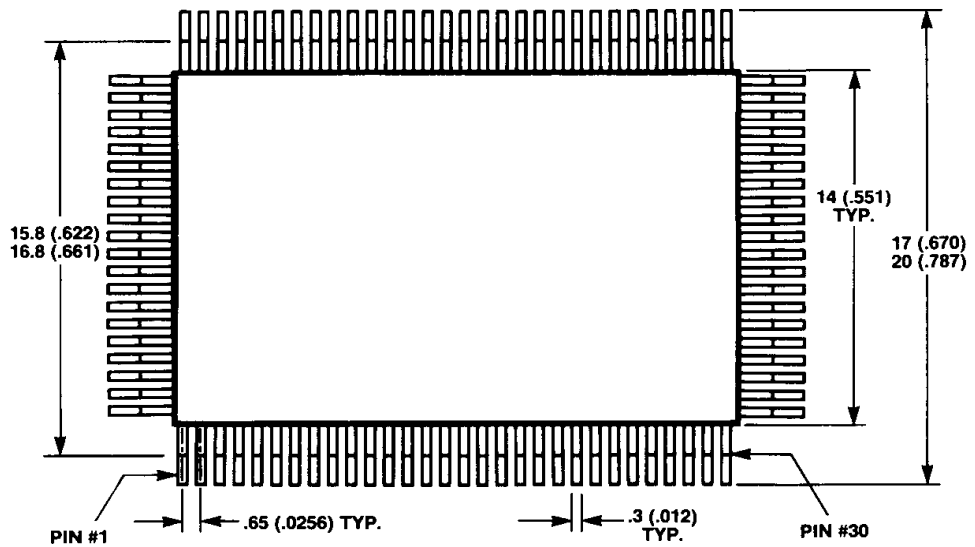
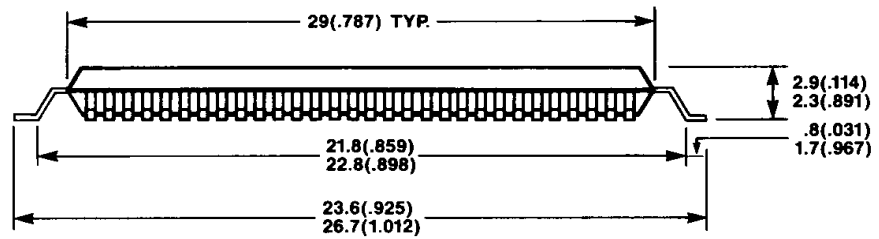


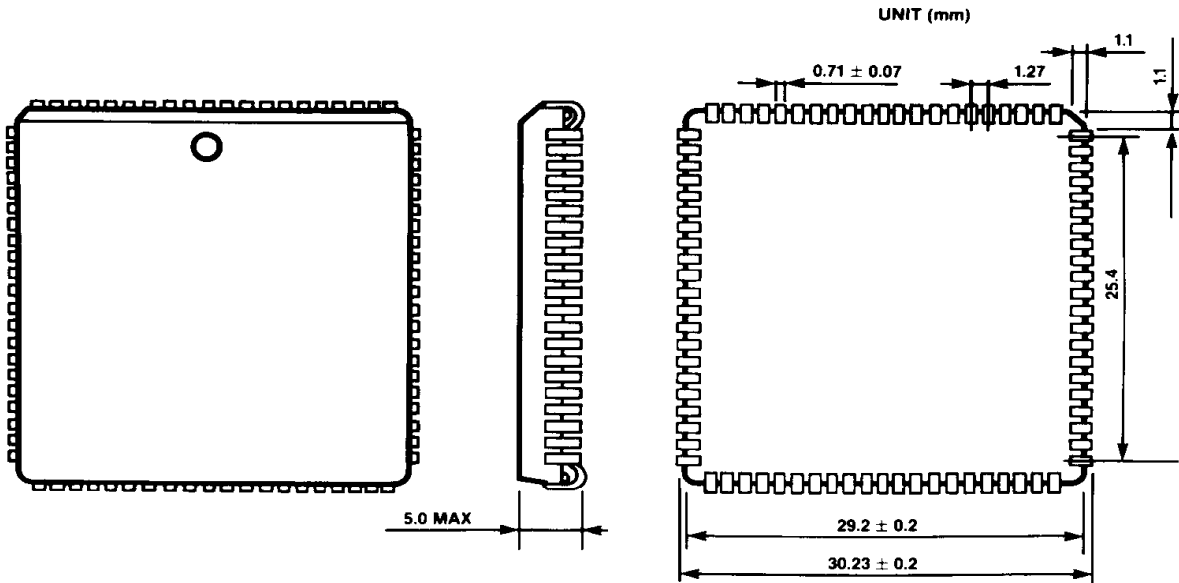
Figure 10. Load Circuit and AC Characteristics Measurement Waveform

100-PIN PLASTIC FLAT PACKAGE



ALL DIMENSIONS IN MILLIMETERS (INCHES).

84-PIN PLASTIC LEADED CHIP CARRIER



Ordering Information

Order Number	Package Type
P82C211/212/215/206	PLCC-84 pins
F82C211/212/215/206	PFP-100 pins

Note:

1. PLCC = Plastic Leaded Chip Carrier
PFP = Plastic Flat Pack

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